8-bit Original Microcontroller cmos

F²MC-8L MB89530 Series

MB89537/537C/538/538C MB89F538L/P538/PV530

■ DESCRIPTION

The MB89530 series is a one-chip microcontroller featuring the F²MC-8L core supporting low-voltage and high-speed operation. Built-in peripheral functions include timers, serial interface, A/D converter, and external interrupt. This product is an ideal general-purpose one-chip microcontroller for a wide variety of applications from household to industrial equipment, as well as use in portable devices.

■ FEATURES

- Wide range of package options
 - QFP package (1mm pitch)
 - Two types of LQFP packages (0.5mm pitch, 0.65mm pitch)
 - SH-DIP package
 - BCC package (0.5mm pitch)
- · Low voltage, high-speed operating capability
 - Minimum instruction execution time 0.32 μs (at base oscillator 12.5MHz)
- F2MC-8L CPU Core
 - Instruction set optimized for controller operation
 - Multiplication/division instructions
 - 16-bit calculation
 - · Branching instructions with bit testing
 - Bit operation instructions, etc.
- Five timer systems
 - 8-bit PWM timer with 2 channels (usable as either interval timer of PWM timer)
 - Pulse width count timer (supports continuous measurement or remote control receiving applications)
 - 16-bit timer counter
 - 21-bit time base timer
 - Watch prescaler (17-bit)
- UART
 - Synchronous or asynchronous operation, switchable
- 2 serial interfaces (serial I/O)
 - Selection of transfer direction (specify MSB first or LSB first) for communication with a variety of devices



(Continued)

- 10-bit A/D converter (8 channels)
 - External clock input for startup support (except for MB89F538L)
 - Time base timer output for startup support
- Pulse generators (PPG) with 2-program capability
 - 6-bit PPG with selection of pulse width and pulse period
 - 12-bit PPG (2 channels) with selection of pulse width and pulse period
- I2C interface circuits
- External interrupt 1 (single-clock : 4 channels, dual-clock : 3 channels)
 - 4 or 3 independent inputs, release enabled from standby mode (includes edge detection function)
- External interrupt 2 (except for MB89F538L : 8 channels, MB89F538L : 7 channels)
 - 8 or 7 independent inputs, release enabled form standby mode (includes level edge detection function)
- Standby modes (low power consumption modes)
 - Stop mode (oscillator stops, virtually no power consumed)
 - Sleep mode (CPU stops, power consumption reduced to one-third)
 - Sub clock mode
 - Watch mode
- Watchdog timer reset
- I/O ports

• Maximum port single-clock : except for MB89F538L : 53

MB89F538L : 52

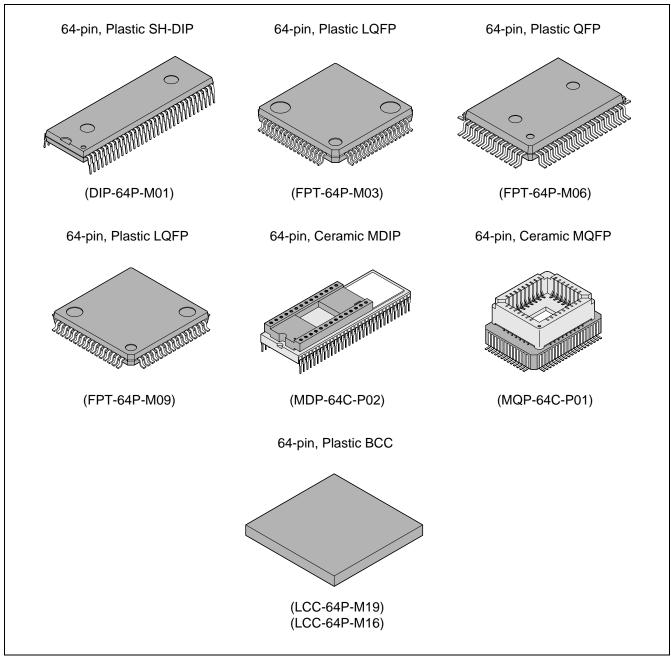
dual-clock : except for MB89F538L : 51

MB89F538L : 50

- 38 general-purpose I/O ports (CMOS) (MB89F538L : 37)
- 2 general-purpose I/O ports (N-ch open drain)
- 8 general-purpose output ports (N-ch open drain)
- General-purpose input ports(CMOS)single-clock : except for MB89F538L : 5

dual-clock : except for MB89F538L : 3

■ PACKAGES



■ PRODUCT LINEUP

Pai	Part number	MB89537/ 537C	MB89538/ 538C	MB89F538L	MB89P538	MB89PV530		
Тур	ре	Mass produce	d (Mask ROM)	FLASH	One-time programmable	Evaluation		
ROM capacity		32 K × 8-bit (built-in ROM)	48 K × 8-bit (built-in ROM)	48 K × 8-bit (built-in FLASH memory) (write from general purpose EPROM writer)	48 K × 8-bit (built-in ROM) (write from general purpose EPROM writer)	48 K × 8-bit (external ROM) *2		
RA	M capacity	1 K × 8-bit		2 K ×	8-bit			
Ор	erating voltage	2.2 V to 3.6 V*1 537C/	•	2.4 V to 3.6 V*1	2.7 V to	5.5 V		
СР	Basic instructions : 136 Instruction bit length : 8-bits Instruction length : 1 bit to 3 bits Data bit length : 1, 8, 16-bits Minimum instruction execution time : 0.32 µs / 12.5 MHz Minimum interrupt processing time : 2.88 µs / 12.5 MHz							
Peripheral functions	Ports	Input ports : single-clock 5 (4 also usable as external interrupts) dual-clock 3 (3 also usable as external interrupts) Output-only ports (N-ch open drain) : 8 (8 also usable as ADC input) I/O ports (N-ch open drain) : 2 (2 also usable as SO2/SDA or SI2/SCL) I/O ports (CMOS) : 38 (21 have no other function) (except for MB89F538L) I/O ports (CMOS) : 37 (21 have no other function) (MB89F538L) Total (except for MB89F538L) : single-clock 53, 2system clock 51 Total (MB89F538L) : single-clock 52, 2system clock 50						
Periphera	Time base timer	21 bits						
	Watchdog timer	Reset period of approx. 167.8 ms to 335.6 ms at mail clock frequency of 12.5 MHz Reset period of approx. 500 ms to 1000 ms at sub clock frequency of 32.768 kHz.						
	PWM timer	8-bit interval timer operation (supports square wave output, operating clock period : 1, 8, 16, 64 t _{inst} *3) Pulse width measurement with 8-bit resolution (conversion period : 2 ⁸ t _{inst} *3 to 2 ⁸ × 64 t _{inst} *3) 2 channels (can also be used as interval timer, can also be used as ch1 output and ch2 count clock)						
Watch prescaler Interval times at 17-bit sub clock base frequency of 32.768 kHz (approx. 31.25 ms, 0.25 s, 0.50 s, 1.00 s, 2.00 s, 4.00 s)								

(Continued)

Part number MB89537/537C MB89538/538C MB89F538L MB89P538 MI									
Pa	rameter								
	Pulse width count timer	8-bit one-shot timer operation (supports underflow output, operating clock period : 1, 4, 32 t _{inst} *3, external) 8-bit reload timer operation (supports square wave output, operating clock period : 1, 4, 32 t _{inst} *3, external) 8-bit pulse width measurement operation (continuous measurement, H width measurement, L width measurement, rise-to-rise, fall-to-fall, H width measurement and rise-to-rise)							
	16-bit timer/ counter		` '	ock period : 1 t _{inst} *3, oct rising, falling, or	,				
	Serial I/O	8 bit length, Selec	tion of LSB first o	r MSB first, Transf	er clock (2, 8, 32 tir	nst*3, external)			
	UART/SIO	bit without parity b	oit) .	us data transfer ca s selection of 14 b	pability (8, 9 bit with aud rate settings.	h parity bit, or 7,8			
Peripheral functions	UART	CLK synchronous/CLK asynchronous data transfer capability (4, 6, 7, 8 bit with parity bit, or 5, 7, 8, 9 bit without parity bit). Built-in baud rate generator provides selection of 14 baud rate settings. External clock output, 2-channel 8-bit PWM timer output also available for baud rate settings.							
Periphe	External interrupt 1	Selection of rising	, falling, or both e	dge detection.	hannel independer tection also availab				
	External interrupt 2	Except for MB89F independent L lev Can be used for re	el detection	·	l detection, MB89F	538L : 7-channel			
	6-bit PPG, 12-bit PPG	Can generate squ 6-bit × 1 channel of		with programmablenels.	e period.				
	I ² C bus interface	specifications.		stem Administrato /530/P538/F538L/	r bus version 1.0 a 537C/538C)	nd Philips I ² C			
	A/D converter	10-bit resolution × 8 channels. A/D conversion functions (conversion time : 60 t _{inst} *3) Supports repeated calls from external clock (except for MB89F538L) Supports repeated calls from internal clock. Standard voltage input provided (AVR)							
(p	Standby modes (power saving modes) Sleep mode, stop mode, sub clock mode, watch mode.								
Pro	Process CMOS								

^{*1 :} Depends on operating frequency.

Note: MB89537/538 have no built-in I²C functions.

To use I²C functions, choose the MB89PV530/P538/F538L/MB89537C/538C.

^{*2 :} Using external ROM and MBM27C512.

^{*3 :} t_{inst} represents instruction execution time. This can be selected as 1/4, 1/8, 1/16, 1/64 of the main clock cycle or 1/2 of the sub clock cycle.

■ MODEL DIFFERENCES AND SELECTION CONSIDERATIONS

Part number Package	MB89537/537C	MB89538/538C	MB89F538L	MB89P538	MB89PV530
Tackage					
DIP-64P-M01	0	0	0	0	Х
FPT-64P-M03	0	0	Х	Х	X
FPT-64P-M06	0	0	0	0	Х
FPT-64P-M09	0	0	0	0	Х
LCC-64P-M19	Х	Х	0	Х	Х
LCC-64P-M16	Х	Х	Х	O*	Х
MDP-64C-P02	Х	Х	Х	Х	0
MQP-64C-P01	Х	Х	Х	Х	0

O: Model-package combination available

X : Model-package combination not available

* : Only for ES

Conversion sockets for pin pitch conversion (manufactured by Sunhayato Corp.) can be used.

Contact: Sunhayato Corp.: TEL: +81-3-3984-7791

FAX : +81-3-3971-0535

E-mail: adapter@sunhayato.co.jp

■ DIFFERENCES AMONG PRODUCTS

1. Memory Capacity

When this product is used in a piggy-back or other evaluation configuration, it is necessary to carefully confirm the differences between the model being used and the product it is evaluating. Particular attention should be given to the following (see " CPU core 1. Memory Space").

- The program ROM area starts from address 4000H on the MB89P538, MB89F538L and MB89PV530 models.
- Note upper limits on RAM, such as stack areas, etc.

2. Current Consumption

- On the MB89PV530, the additional current consumed by the EPROM is added at the connecting socket on the back side.
- When operating at low speed, the current consumption in the one-time PROM or EPROM models is greater than on the mask ROM models. However, current consumption in sleep or stop modes is identical.

For details, refer to "ELECTRICAL CHARACTERISTICS".

3. Mask Options

The options available for use, and the method of specifying options, differ according to the model. Before use, check the "MASK OPTIONS" specification section.

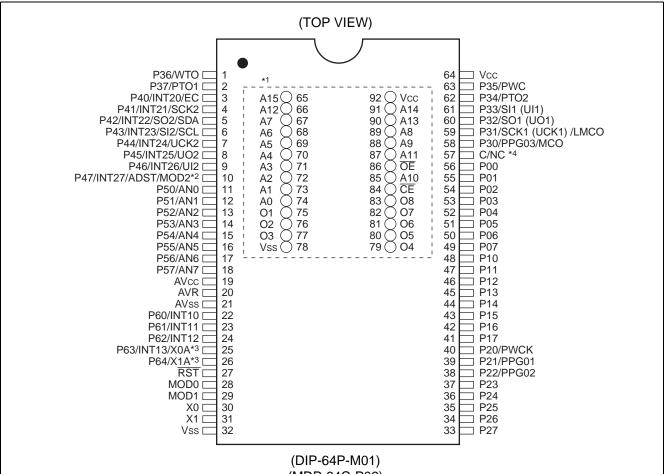
4. Wild Register Functions

The following table shows areas in which wild register functions can be used.

Wild Register Usage Areas

Part number	Address space
MB89PV530	4000н to FFFFн
MB89P538	4000н to FFFFн
MB89F538L	4000н to FFFFн
MB89537/537C	8000н to FFFFн
MB89538/538C	4000н to FFFFн

■ PIN ASSIGNMENTS



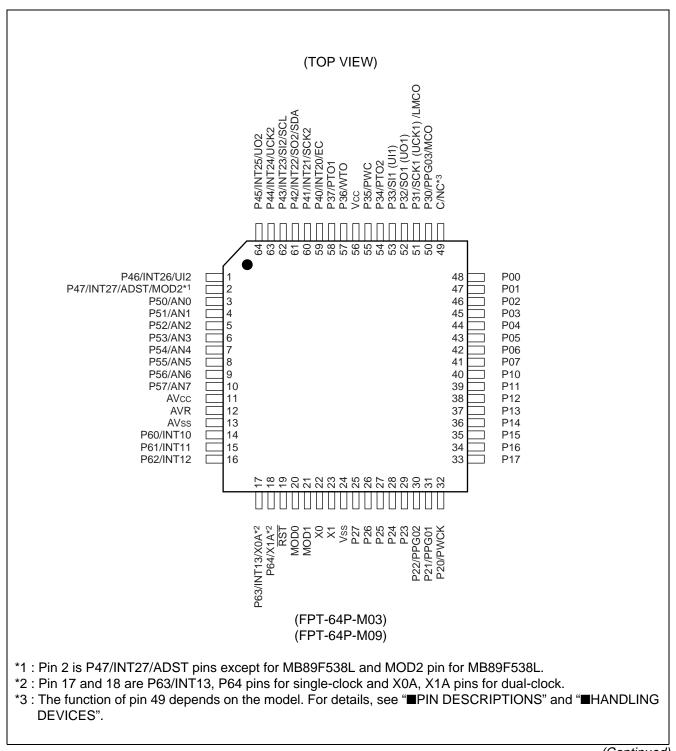
(MDP-64C-P02)

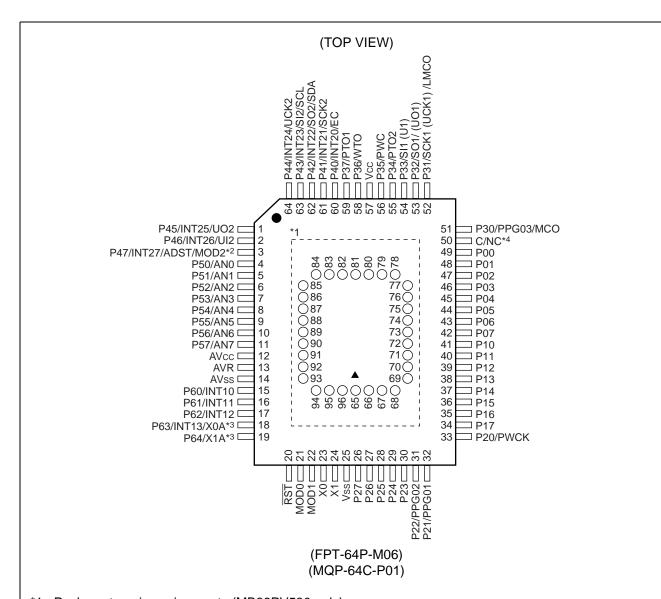
*1 : Package top pin assignments (MB89PV530 only)

Pin no.	Pin name						
65	A15	73	A1	81	O6	89	A8
66	A12	74	A0	82	07	90	A13
67	A7	75	01	83	O8	91	A14
68	A6	76	O2	84	CE	92	Vcc
69	A5	77	O3	85	A10		
70	A4	78	Vss	86	ŌĒ		
71	А3	79	O4	87	A11		
72	A2	80	O5	88	A9		

N.C.: Internal connection only. Not for use.

- *2: Pin 10 is P47/INT27/ADST pins except for MB89F538L and MOD2 pin for MB89F538L.
- *3: Pin 25 and 26 are P63/INT13, P64 pins for single-clock and X0A, X1A pins for dual-clock.
- *4 : The function of pin 57 depends on the model. For details, see "■PIN DESCRIPTIONS" and "■HANDLING DEVICES".





*1 : Package top pin assignments (MB89PV530 only)

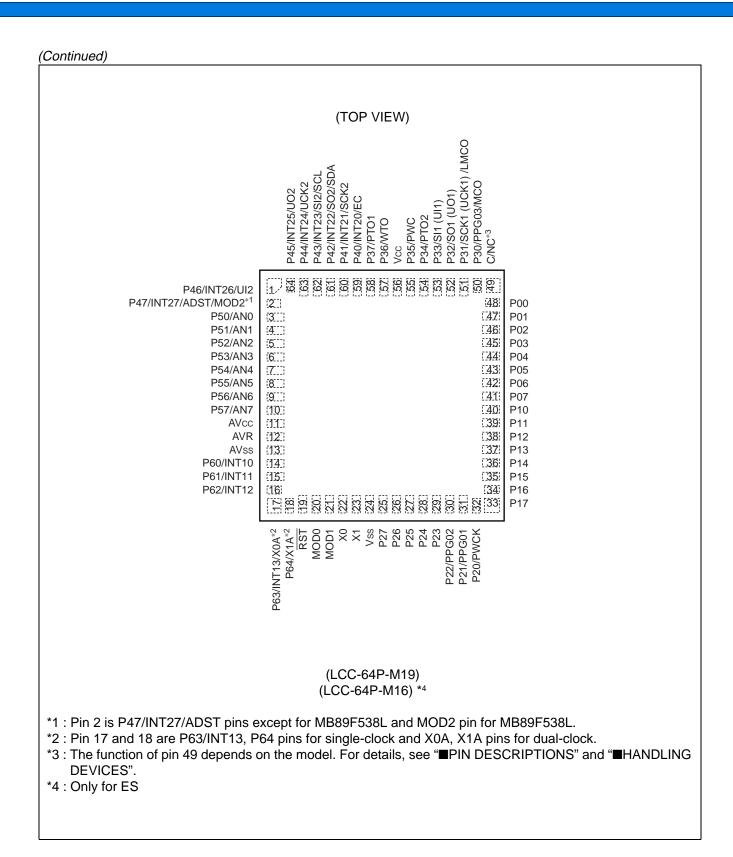
Pin no.	Pin name						
65	N.C.	73	A2	81	N.C.	89	OE
66	A15	74	A1	82	O4	90	N.C.
67	A12	75	A0	83	O5	91	A11
68	A7	76	N.C.	84	O6	92	A9
69	A6	77	01	85	07	93	A8
70	A5	78	O2	86	O8	94	A13
71	A4	79	O3	87	CE	95	A14
72	A3	80	Vss	88	A10	96	Vcc

N.C.: Internal connection only. Not for use.

^{*2 :} Pin 3 is P47/INT27/ADST pins except for MB89F538L and MOD2 pin for MB89F538L.

^{*3 :} Pin 18 and 19 are P63/INT13, P64 pins for single-clock and X0A, X1A pins for dual-clock.

^{*4 :} The function of pin 50 depends on the model. For details, see "■PIN DESCRIPTIONS" and "■HANDLING DEVICES".



■ PIN DESCRIPTIONS

Pin no.		I/O			
SH-DIP*1 MDIP*2	QFP*3 MQFP*4	LQFP*5 BCC*6	Pin name	circuit type	Function
30	23	22	X0		Connecting pins to crystal oscillator circuit or other os-
31	24	23	X1	Α	cillator circuit. The X0 pin can connect to an external clock. In that case, X1 is left open.
28	21	20	MOD0	В	Input pins for memory access mode setting. Connect di-
29	22	21	MOD1	ם	rectly to Vss.
27	20	19	RST	С	Reset I/O pin. This pin has pull-up resistance with CMOS I/O or hysteresis input. At an internal reset request, an 'L' signal is output. An 'L' level input initializes the internal circuits.
56 to 49	49 to 42	48 to 41	P00 to P07	D	General purpose I/O ports.
48 to 41	41 to 34	40 to 33	P10 to P17	D	General purpose I/O ports.
40	33	32	P20/PWCK	E	General purpose I/O port.Resource I/O pin (hysteresis input).Hysteresis input. This pin also functions as a PWC input.
39	32	31	P21/ PPG01	D	General purpose I/O port. This pin also functions as the PPG01 output.
38	31	30	P22/ PPG02	D	General purpose I/O port. This pin also functions as the PPG02 output.
37	30	29	P23	D	General purpose I/O port.
36	29	28	P24	D	General purpose I/O port.
35	28	27	P25	D	General purpose I/O port.
34	27	26	P26	D	General purpose I/O port.
33	26	25	P27	D	General purpose I/O port.
58	51	50	P30/ PPG03/ MCO	D	General purpose I/O port. This pin also functions as the PPG03 output.
59	52	51	P31/SCK1 (UCK1)/ LMCO	E	General purpose I/O port.Resource I/O pin (hysteresis input).This pin also functions as the UART/SIO clock input/output pin.
60	53	52	P32/SO1 (UO1)	D	General purpose I/O port. This pin also functions as the UART/SIO clock input/output pin.
61	54	53	P33/SI1 (UI1)	E	General purpose I/O port.Resource input/output pin (hysteresis input).This pin also functions as the UART/ SIO serial data input pin.
62	55	54	P34/PTO2	D	General purpose I/O port. This pin also functions as the PWM time 2 output pin.
63	56	55	P35/PWC	E	General purpose I/O port.Resource I/O pin (hysteresis input).This pin also functions as a PWC input.

Pin no.		I/O				
SH-DIP*1 MDIP*2	QFP*3 MQFP*4	LQFP*5 BCC*6	Pin name	circuit type	Function	
1	58	57	P36/WTO	D	General purpose I/O port.Resource output.This pin also functions as the PWC output pin.	
2	59	58	P37/PTO1	D	General purpose I/O port.Resource output.This pin also functions as the PWM timer 1 output pin.	
3	60	59	P40/INT20/ EC	E	General purpose I/O port.Resource I/O pin (hysteresis input)This pin also functions as an external interrupt input or 16-bit timer/counter input.	
4	61	60	P41/INT21/ SCK2	E	General purpose I/O port.Resource I/O pin (hysteresis input)This pin also functions as an external interrupt input or SIO clock I/O pin.	
5	62	61	P42/INT22/ SO2/SDA	G	N-ch open drain output. Resource I/O pin (hysteresis only for INT22 input) . This pin also functions as an external interrupt input, SIO serial data output, or I ² C data line.	
6	63	62	P43/INT23/ SI2/SCL	G	N-ch open drain output. Resource I/O pin (hysteresis only for INT23 input) . This pin also functions as an external interrupt, SIO serial data input, or I ² C clock I/O pin.	
7	64	63	P44/INT24/ UCK2	E	General purpose I/O port. Resource I/O pin (hysteresis input) . This pin also functions as an external interrupt input or UART clock I/O pin.	
8	1	64	P45/INT25/ UO2	E	General purpose I/O port. Resource I/O pin (hysteresis input) . This pin also functions as an external interrupt input or UART data output pin.	
9	2	1	P46/INT26/ UI2	E	General purpose I/O port. Resource I/O pin (hysteresis input) . This pin also functions as an external interrupt input or UART data input pin.	
10	3	2	P47/INT27/ ADST	E	except for Resource I/O pin (hysteresis input) . MB89F This pin also functions as an external interrupt input or A/D converter clock input pin.	
			MOD2	В	MB89F Input pin for memory access mode setting. 538L Connect to Vss directly.	
11 to 18	4 to 11	3 to 10	P50/AN0 to P57/AN7	Н	N-ch open drain output port. This pin also functions as an A/D converter analog input pin.	
22 to 24	15 to 17	14 to 16	P60/INT10 to P62/INT12	I	General purpose input port. Resource input pin (hysteresis input) . This pin also functions as an external interrupt input pin.	

(Continued)

	Pin no.		I/O			
SH-DIP*1 MDIP*2	QFP*3 MQFP*4	LQFP*5 BCC*6	Pin name	circuit type	Function	
25	18	17	P63/INT13	I	Single-clock	General purpose input port. Resource input pin (hysteresis input). This pin also functions as an external interrupt.
			X0A	Α	Dual-clock	Connected pin for sub clock.
26	19	18	P64	J	Single-clock	General purpose input port.
20	19	10	X1A	Α	Dual-clock	Connected pin for sub clock.
64	57	56	Vcc		Power supply pin.	
32	25	24	Vss		Ground pin (GND) .	
19	12	11	AVcc		A/D converter power supp	ly pin.
20	13	12	AVR		A/D converter reference vo	oltage input pin.
21	14	13	AVss	_	A/D converter power supply pin. Used at the same voltage level as the Vss supply.	
					MB89P538	Fixed at Vss.
57	50	49	С		MB89PV530 MB89F538L MB89537/537C MB89538/538C	N.C. pin

*1 : DIP-64P-M01

*2: MDP-64C-P02

*3: FPT-64P-M06

*4: MQP-64C-P01

*5: FPT-64P-M03/M09

*6: LCC-64P-M19/M16

External EPROM Socket Pin Function Descriptions (MB89PV530 only)

	no.		I/O Circuit	ons (MB89PV530 only)
MDIP*1	MQFP*2	Pin name	type	Function
65 66 67 68 69 70 71 72 73	66 67 68 69 70 71 72 73 74 75	A15 A12 A7 A6 A5 A4 A3 A2	0	Address output pins.
74 75 76 77	75 77 78 79	A0 O1 O2 O3	I	Data input pins.
78	80	Vss	0	Power supply pin (GND) .
79 80 81 82 83	82 83 84 85 86	O4 O5 O6 O7 O8	I	Data input pins.
84	87	CE	0	ROM chip enable pin. Outputs an "H" level signal in standby mode.
85	88	A10	0	Address output pin.
86	89	ŌĒ	0	ROM output enable pin. Outputs "L" at all times.
87 88 89	91 92 93	A11 A9 A8	0	Address output pins.
90	94	A13	0	
91	95	A14	0	
92	96	Vcc	0	EPROM power supply pin.
_	65 76 81 90	N.C.	0	Internally connected. These pins always left open.

*1 : MDP-64C-P02

*2: MQP-64C-P01

■ I/O CIRCUIT TYPES

Туре	Circuit	Remarks
А	X1 (X1A) Nch Pch X0 (X0A) Nch Pch Nch Pch	Oscillator feedback resistance • High speed side = approx. 1 $M\Omega$ • Low speed side = approx. 10 $M\Omega$
В		 Hysteresis input Pull-down resistance built-in to MB89537/537C MB89538/538C
С	R Pch Nch	 Pull-up resistance approx. 50 kΩ Hysteresis input
D	Pull-up control resistor	 CMOS I/O Software pull-up resistance can be used. Approx. 50 kΩ
E	Pull-up control resistors	 CMOS I/O Software pull-up resistance can be used. Approx. 50 kΩ
	Port input Resource input	

Туре	Circuit	Remarks
G	Nch Resource input Port input	N-ch open drain outputHysteresis inputCMOS input
Н	Pch Nch Analog input	 N-ch open drain output Analog input (A/D converter)
I	Pull-up control resistors Resource Port	 Hysteresis input CMOS input Software pull-up resistance can be used. Approx. 50 kΩ
J	Pull-up control resistors Port	 CMOS input Software pull-up resistance can be used. Approx. 50 kΩ

■ HANDLING DEVICES

1. Preventing Latchup

Care must be taken to ensure that maximum voltage ratings are not exceeded (to prevent latchup). When CMOS integrated circuit devices are subjected to applied voltages higher than Vcc at input and output pins (other than medium- and high-withstand voltage pins), or to voltages lower than Vss, as well as when voltages in excess of rated levels are applied between Vcc and Vss, the phenomenon known as latchup can occur.

When a latchup condition occurs, supply current can increase dramatically and may destroy semiconductor elements. In using semiconductor devices, always take sufficient care to avoid exceeding maximum ratings.

Also when switching power on or off to analog systems, care must be taken that analog power supplies (AVCC, AVR) and analog input signals do not exceed the level of the digital power supply.

2. Power Supply Voltage Fluctuations

Keep supply voltage levels as stable as possible.

Even within the warranted operating range of the Vcc supply voltage, sudden changes in supply voltage can cause abnormal operation. As a measure for stability, it is recommended that the Vcc ripple fluctuation (peak to peak value) should be kept within 10% of the reference Vcc value on commercial power supply (50 Hz-60 Hz), and instantaneous voltage fluctuations such as at power-on and shutdown should be kept within a transient variability limit of 0.1V/ms.

3. Treatment of Unused Input Pins

If unused input pins are left open, abnormal operation may result. Any unused input pins should be connected to pull-up or pull-down resistance.

4. Treatment of N.C. Pins

Any pins marked 'NC' (not connected) must be left open.

5. Treatment of Power Supply Pins on Models with Built-in A/D Converter

Even when A/D converters are not in use, pins should be connected so that AVcc = Vcc, and AVss = AVR = Vss.

6. Precautions for Use of External Clock

Even when an external clock signal is used, an oscillator stabilization wait period is used after power-on reset, or escape from sub clock mode or stop mode.

7. Execution of Programs on RAM

Debugging of programs executed on RAM cannot be performed even when using the MB89PV530.

8. Wild Register Functions

Wild registers cannot be debugged with the MB89PV530 and tools. To verify operations, actual in-device testing on the MB89P538 or MB89F538L is advised.

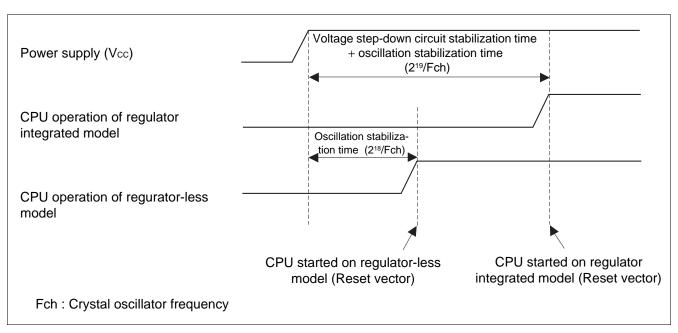
9. Details on Handling C Terminal of MB89530 Series

The MB89530 series contains the following products. The regulator integrated model and the regulator-less model have different performance characteristics.

Part No.	Operation Voltage	integrated model	Terminal type	Terminal treatments
MB89PV530		Not included	N.C terminal	Not required
MB89P538	2.7 V to 5.5 V	Included	C terminal	Fixed to Vcc
			Cteminal	Fixed to Vss
MB89537/537C	2.2 V to 3.6 V	Not included		Not required
MB89538/538C	2.2 V 10 3.6 V	Not included	N.C terminal	
MB89F538L	2.3 V to 3.6 V			

Although these product models have the same internal resources, the operation sequence after a power-on reset is different between the regulator integrated model and regulator-less model.

The operation sequence after a power-on reset of each model is shown below.



As above, the regulator integrated model starts the CPU behind the regulator-less model. This is because the regulator requires a settling time for normal operation.

The MB89P538 offers a choice of regulator-integrated and regulator-less models selectable depending on the C-terminal treatment. Use the right one for your mask board.

10. Note to Noise In the External Reset Pin (RST)

If the reset pulse applied to the external reset pin (\overline{RST}) does not meet the specifications, it may cause malfunctions. Use caution so that the reset pulse less than the specifications will not be fed to the external reset pin (\overline{RST}) .

■ PROGRAMMING AND ERASING FLASH MEMORY ON THE MB89F538L

1. Flash Memory

The flash memory is located between 4000_H and FFFF_H in the CPU memory map and incorporates a flash memory interface circuit that allows read access and program access from the CPU to be performed in the same way as mask ROM. Programming and erasing flash memory is also performed via the flash memory interface circuit by executing instructions in the CPU. This enables the flash memory to be updated in place under the control of the CPU, providing an efficient method of updating program and data.

2. Flash Memory Features

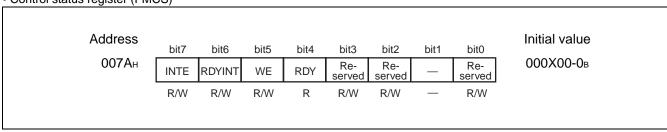
- 48 K byte×8-bit configuration : (16 K+8 K+8 K+16 K sectors)
- Automatic programming algorithm (Embedded algorithm* : Equivalent to MBM29LV200)
- Includes an erase pause and restart function
- Data polling and toggle bit for detection of program/erase completion
- Detection of program/erase completion via CPU interrupt
- Compatible with JEDEC-standard commands
- Sector Erasing (sectors can be combined in any combination)
- No. of program/erase cycles: 10,000 (Min)

3. Procedure for Programming and Erasing Flash Memory

Programming and reading flash memory cannot be performed at the same time. Accordingly, to program or erase flash memory, the program must first be copied from flash memory to RAM so that programming can be performed without program access from flash memory.

4. Flash Memory Register

• Control status register (FMCS)



^{*:} Embedded Algorithm is a trademark of Advanced Micro Devices.

5. Sector Configuration

The table below shows the sector configuration of flash memory and lists the addresses of each sector for both during CPU access a flash memory programming.

• Sector configuration of flash memory

FLASH Memory	CPU Address	Programmer Address*
16 K bytes	FFFF _H to C000 _H	1FFFFн to 1С000н
8 K bytes	BFFFн to A000н	1BFFFн to 1A000н
8 K bytes	9FFFн to 8000н	19FFFн to 18000н
16 K bytes	7FFFн to 4000н	17FFFн to 14000н

^{* :} The programmer address is the address to be used instead of the CPU address when programming data from a parallel flash memory programmer. Use the programmer address on programming or erasing using a general-purpose parallel programmer.

6. ROM Programmer Adaptor and Recommended ROM Programmers

Part number	Package	Adaptor Part No.	Recommended Programmer Manufacturer and Model	
	_	Sunhayato Corp.	Ando Electric Co., Ltd.	
MB89F538L-101PF MB89F538L-201PF	FPT-64P-M06	FLASH-64QF-32DP-8LF		
MB89F538L-101PFM MB89F538L-201PFM	FPT-64P-M09	FLASH-64QF2-32DP-8LF2	AF9708*	
MB89F538L-101P-SH MB89F538L-201P-SH	DIP-64P-M01	FLASH-64SD-32DP-8LF	AF9709*	
MB89F538L-101PV4 MB89F538L-201PV4	LCC-64P-M19	FLASH-64BCC-32DP-8LF		

^{*:} For the version of the programmer, contact the Flash Support Group, Inc.

• Enquiries

Sunhayato Corp. : TEL : +81-3-3984-7791 FAX : +81-3-3971-0535

E-mail: adapter@sunhayato.co.jp

Flash Support Group, Inc.: FAX: +81-53-428-8377

E-mail: support@j-fsg.co.jp

■ ONE-TIME WRITING SPECIFICATIONS WITH PROM AND EPROM MICROCONTROLLERS

The MB89P538 has a PROM mode with functions equivalent to the MBM27C1001, allowing writing with a general purpose ROM writer using a proprietary adapter. Note, however, that the use of electronic signature mode is not supported.

• ROM writer adapters

With some ROM writers, stability of writing performance is enhanced by placing an $0.1\mu F$ capacitor between the Vcc and Vss pins. The following table lists adapters for use with ROM writers.

ROM Writer Adapters

Part number	Package	Compatible adapter	
MB89P538-101PF MB89P538-201PF	FPT-64P-M06	ROM-64QF-32DP-8LA2*1	
MB89P538-101PFM MB89P538-201PFM	FPT-64P-M09	ROM-64QF2-32DP-8LA	
MB89P538-101P-SH MB89P538-201P-SH	DIP-64P-M01	ROM-64SD-32DP-8LA2*1	
MB89P538-101P-PV MB89P538-201P-PV	LCC-64P-M16*2	ROM-64BCC-32DP-8LA-FJ	

Inquiries should be addressed to

Sunhayato Corp. : TEL : +81-3-3984-7791 FAX : +81-3-3971-0535

FAX . +01-3-39/1-0535

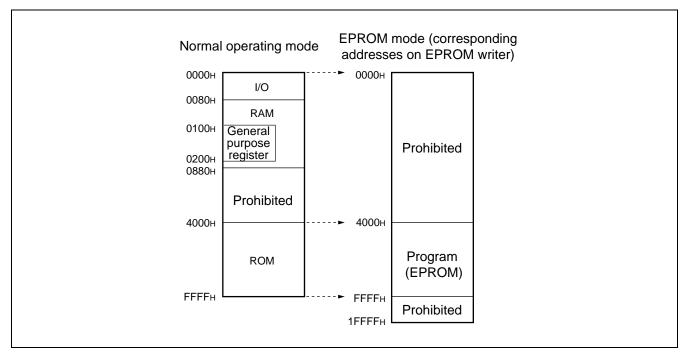
E-mail: adapter@sunhayato.co.jp

*1: Version 3 or later should be used.

*2 : Only for ES

• Memory map for EPROM mode

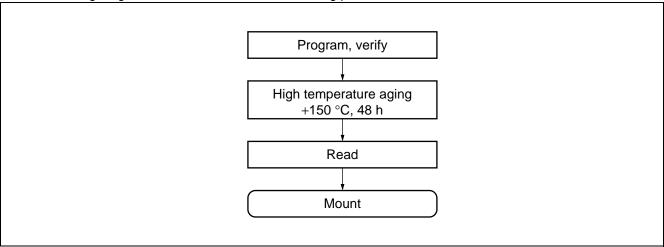
The following illustration shows a memory map for EPROM mode. There are no PROM options.



• Recommended screening conditions

Before one-time writing of microcontroller programs to PROM, high temperature aging is recommended as a screening process for chips before they are mounted.

The following diagram shows the flow of the screening process.



• About writing yields

The nature of chips before one-time writing of microcontroller programs to PROM prevents the use of all-bit writing tests. Therefore it is not possible to guarantee writing yields of 100% in some cases.

■ EPROM WRITING TO PIGGY-BACK/EVALUATION CHIPS

This section describes methods of writing to EPROM on piggy-back/evaluation chips.

• EPROM model

MBM27C512-20TV

• Writer adapter

For writing to EPROM using a ROM writer, use one of the writer adapters shown below (manufactured by Sunhayato Corp.).

Package	Adapter socket model	
LCC-32 (rectangular)	ROM-32LC-28DP-YG	

Inquiries should be addressed to

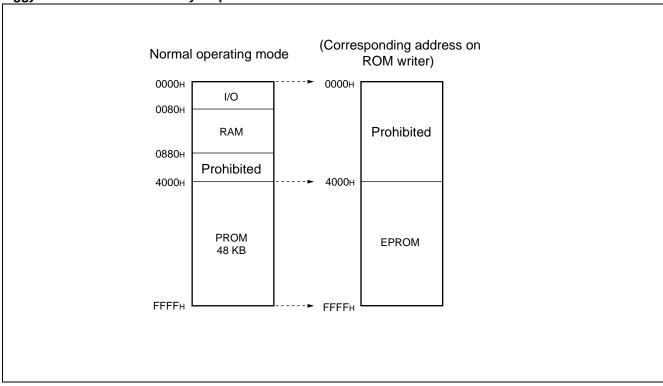
Sunhayato Corp. : TEL : +81-3-3984-7791

FAX: +81-3-3971-0535

E-mail: adapter@sunhayato.co.jp

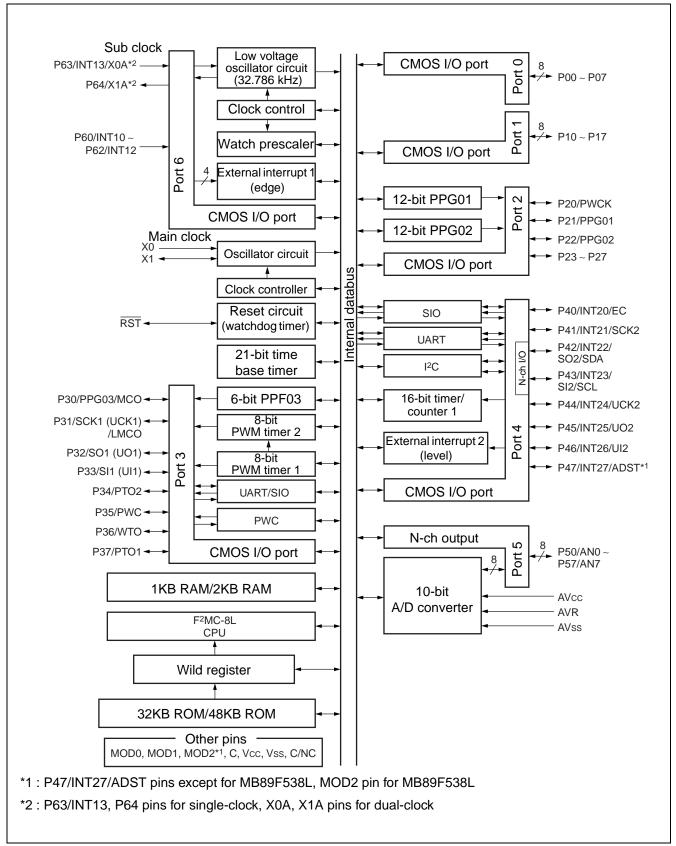
Memory Space

Piggy-back/Evaluation Memory Map



- Writing to EPROM
 - 1) Set up the EPROM writer for the MBM27C512.
 - 2) Load program data to the ERPOM writer, in the area 4000H FFFFH.
 - 3) Use the EPROM writer to write to the area 4000_H FFFF_H.

■ BLOCK DIAGRAM

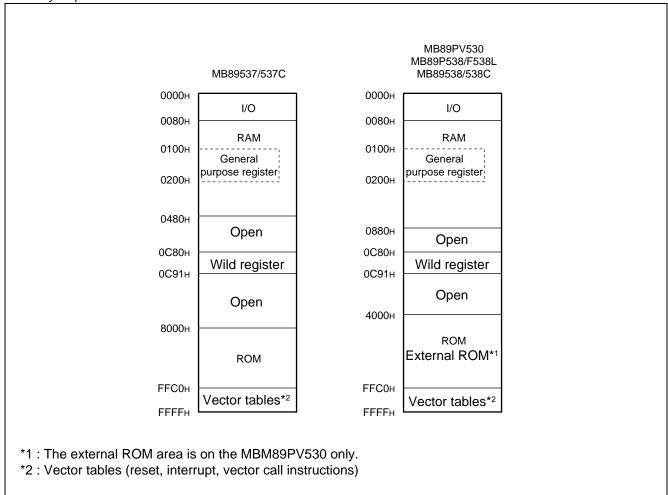


■ CPU CORE

1. Memory Space

The MBM89530 series has 64 KB of memory space, containing all I/O, data areas, and program areas. The I/O area is located at the lowest addresses, with the data area placed immediately above. The data area can be partitioned into register areas, stack areas, or direct access areas depending on the application. The program area is located at the opposite end of memory, closest to the highest addresses, and the highest part of this area is assigned to the tables of interrupt and reset vectors and vector call instructions. The following diagram shows the structure of memory space in the MB89530 series.





2. Registers

The F²MC-8L series has two types of registers, dedicated-use registers within the CPU, and general-purpose registers in memory.

The dedicated-use registers are the following.

Program counter (PC) : 16-bit length, shows the location where instructions are stored.

Accumulator (A) : 16-bit length, a temporary memory register for calculation operations.

The lower byte is used for 8-bit data processing instructions.

Temporary accumulator (T) : 16-bit length, performs calculations with the accumulator.

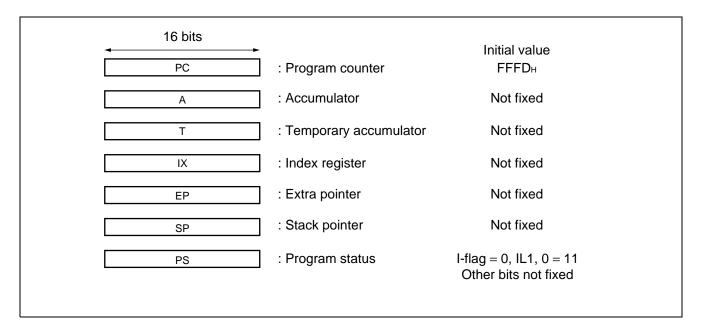
The lower byte is used for 8-bit data processing instructions.

Index register (IX) : 16-bit length, a register for index modification.

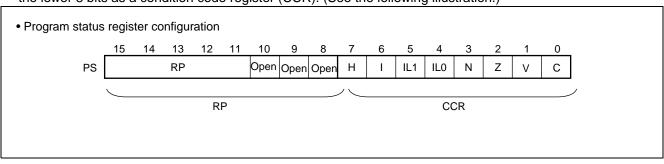
Extra pointer (EP) : 16-bit length, a pointer indicating memory addresses.

Stack pointer (SP) : 16-bit length, indicates stack areas.

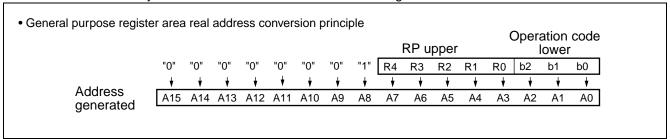
Program status (PS) : 16-bit length, contains register pointer and condition code.



In addition, the PS register can be divided so that the upper 8 bits are used as a register bank pointer (RP), and the lower 8 bits as a condition code register (CCR). (See the following illustration.)



The RP register shows the address of the register bank currently being used, so that the RP value and the actual address are related by the conversion rule shown in the following illustration.



The CCR register has bits that show the content of results of calculations and transferred data, and bits that control CPU operation during interrupts.

H-flag : Set to 1 if calculations result in carry or borrow operations from bit 3 to bit 4, otherwise set to 0.

This flag is used for decimal correction instructions.

I-flag : This flag is set to 1 if interrupts are enabled, and 0 if interrupts are prohibited.

The default value at reset is 0.

IL1, 0 : Indicates the level of the currently permitted interrupts.

Only interrupt requests having a more powerful level than the value of these bits will be processed.

IL1	IL0	Interrupt level	Strength
0	0	1	Strong
0	1	ľ	†
1	0	2	
1	1	3	Weak

N-flag : Set to 1 if the highest bit is 1 after a calculation, otherwise cleared to 0.

Z-flag : Set to 1 if a calculation result is 0, otherwise cleared to 0.

V-flag : Set to 1 if a two's complement overflow results during a calculation, otherwise cleared to 0.

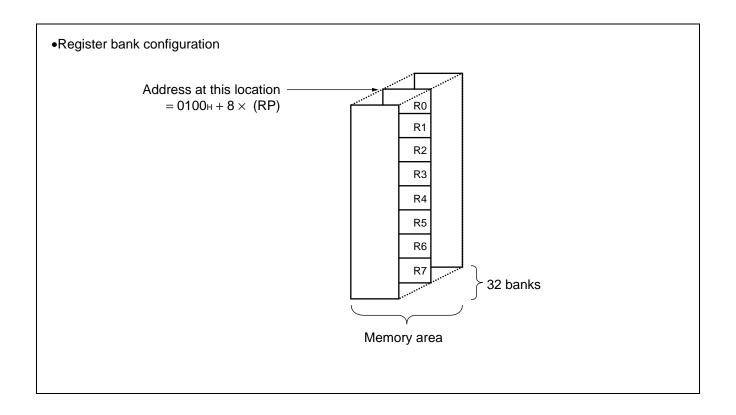
C-flag : Set to 1 if a calculation results in a carry or borrow operation from bit 7, otherwise cleared to 0.

This is also the shift-out value in a shift instruction.

In addition, the following general purpose registers are available.

General purpose registers: 8-bit length, used to contain data.

The general purpose registers are 8-bit registers located in memory. There are eight such registers per bank, and the MB89530 series have up to 32 banks for use. The bank currently in use is indicated by the register bank pointer (RP).



■ I/O MAP

Address	Register name	Register description	Write/Read	Initial value
00н	PDR0	Port 0 data register	R/W	XXXXXXXX
01н	DDR0	Port 0 direction register	W	00000000
02н	PDR1	Port 1 data register	R/W	XXXXXXXX
03н	DDR1	Port 1 direction register	W	00000000
04н to 06н		(Reserved area)	'	1
07н	SYCC	System clock control register	R/W	Х-1 ММ1 0 Ов
08н	STBC	Standby control register	R/W	00010в
09н	WDTC	Watchdog control register	R/W	0XXXXB
0Ан	TBTC	Time base timer control register	R/W	00000в
0Вн	WPCR	Watch prescaler control register	R/W	000000в
0Сн	PDR2	Port 2 data register	R/W	XXXXXXXX
0Dн	DDR2	Port 2 direction register	R/W	00000000
0Ен	PDR3	Port 3 data register	R/W	XXXXXXXX
0Fн	DDR3	Port 3 direction register	R/W	00000000
10н	PDR4	Port 4 data register	R/W	XXXX11XX _B
11н	DDR4	Port 4 direction register	R/W	000000в
12н	PDR5	Port 5 data register	R/W	11111111
13н	PDR6	Port 6 data register	R	XXXXXXXX
14н to 21н		(Reserved area)		
22н	SMC11	Serial mode control register 1 (UART)	R/W	0000000B
23н	SRC1	Serial route control register (UART)	R/W	011000в
24н	SSD1	Serial status and data register (UART)	R/W	00100-1Xв
25н	SIDR1/ SODR1	Serial input/output data register (UART)	R/W	XXXXXXXXB
26н	SMC12	Serial mode control register 2 (UART)	R/W	100001в
27н	CNTR1	PWM control register 1	R/W	00000000
28н	CNTR2	PWM control register 2	R/W	000-0000в
29н	CNTR3	PWM control register 3	R/W	-000в
2Ан	COMR1	PWM compare register 1	W	XXXXXXXX
2Вн	COMR2	PWM compare register 2	W	XXXXXXXX
2Сн	PCR1	PWC pulse width control register 1	R/W	000000в
2Dн	PCR2	PWC pulse width control register 2	R/W	00000000
2Ен	RLBR	PWC reload buffer register	R/W	XXXXXXXX
2Fн	SMC21	Serial mode control register 1 (UART/SIO)	R/W	00000000
30н	SMC22	Serial mode control register 2 (UART/SIO)	R/W	00000000
31н	SSD2	Serial status and data register (UART/SIO)	R/W	00001в
32н	SIDR2/ SODR2	Serial data register (UART/SIO)	R/W	XXXXXXXXB

Address	Register name	Register description	Write/Read	Initial value
33н	SRC2	Baud rate generator reload register	R/W	XXXXXXXX
34н	ADC1	A/D control register 1	R/W	000000-0в
35н	ADC2	A/D control register 2	R/W	-0000001в
36н	ADDL	A/D data register low	R/W	XXXXXXXX
37н	ADDH	A/D data register high	R/W	О Ов
38н	PPGC2	PPG2 control register (12-bit PPG)	R/W	0000000B
39н	PRL22	PPG2 reload register 2 (12-bit PPG)	R/W	0Х00000В
ЗАн	PRL21	PPG2 reload register 1 (12-bit PPG)	R/W	XX000000B
3Вн	PRL23	PPG2 reload register 3 (12-bit PPG)	R/W	XX000000B
3Сн	TMCR	16-bit timer control register	R/W	000000в
3Dн	TCHR	16-bit timer counter register high	R/W	0000000B
3Ен	TCLR	16-bit timer counter register low	R/W	0000000B
3Fн	EIC1	External interrupt 1 control register 1	R/W	0000000B
40н	EIC2	External interrupt 1 control register 2	R/W	0000000B
41н to 48н		(Reserved area)	•	1
49н	DDCR	DDC select register	R/W	0 _B
4Ан to 4Вн		(Reserved area)	•	1
4Сн	PPGC1	PPG1 control register (12-bit PPG)	R/W	0000000B
4Dн	PRL12	PPG1 reload register 2 (12-bit PPG)	R/W	0Х00000В
4 Ен	PRL11	PPG1 reload register 1 (12-bit PPG)	R/W	XX000000B
4 Fн	PRL13	PPG1 reload register 3 (12-bit PPG)	R/W	XX000000B
50н	IACR	I ² C address control register	R/W	000В
51н	IBSR	I ² C bus status register	R	0000000B
52н	IBCR	I ² C bus control register	R/W	0000000B
53н	ICCR	I ² C clock control register	R/W	000XXXXXB
54 н	IADR	I ² C address register	R/W	-XXXXXXXB
55н	IDAR	I ² C data register	R/W	XXXXXXXX
56н	EIE2	External interrupt 2 control register	R/W	0000000B
57н	EIF2	External interrupt 2 flag register	R/W	Ов
58н	RCR1	6-bit PPG control register 1	R/W	0000000B
59н	RCR2	6-bit PPG control register 2	R/W	0Х00000В
5Ан	CKR	Clock output control register	R/W	00в
5Вн to 6Fн		(Reserved area)	•	•
70н	SMR	Serial mode register (SIO)	R/W	0000000B
71н	SDR	Serial data register (SIO)	R/W	XXXXXXXXB
72н	PURR0	Port 0 pull-up resistance register	R/W	11111111
73н	PURR1	Port 1 pull-up resistance register	R/W	11111111
74н	PURR2	Port 2 pull-up resistance register	R/W	11111111
75н	PURR3	Port 3 pull-up resistance register	R/W	11111111

(Continued)

Address	Iress Register Register description		Write/Read	Initial value	
76н	PURR4	Port 4 pull-up resistance register	R/W	111111в	
77н	WREN	Wild register enable register	R/W	000000в	
78н	WROR	Wild register data test register	R/W	000000в	
79н	PURR6	Port 6 pull-up resistance register	R/W	111111в	
7Ан	FMCS	FLASH control status register	R/W	000Х00 - 0 в	
7Вн	ILR1	Interrupt level setting register 1	W	11111111	
7Сн	ILR2	Interrupt level setting register 2	W	11111111	
7Dн	ILR3	Interrupt level setting register 3	W	11111111	
7Е н	ILR4	Interrupt level setting register 4	W	11111111	
7 Fн	ITR	Interrupt test register	Access prohibited	XXXXXXX 0 0 _B	
С80н	WRARH1	Upper address setting register 1	R/W	XXXXXXX	
С81н	WRARL1	Lower address setting register 1	R/W	XXXXXXX	
С82н	WRDR1	Data setting register 1	R/W	XXXXXXX	
С83н	WRARH2	Upper address setting register 2	R/W	XXXXXXX	
С84н	WRARL2	Lower address setting register 2	R/W	XXXXXXX	
С85н	WRDR2	Data setting register 2	R/W	XXXXXXX	
С86н	WRARH3	Upper address setting register 3	R/W	XXXXXXX	
С87н	WRARL3	Lower address setting register 3	R/W	XXXXXXX	
С88н	WRDR3	Data setting register 3	R/W	XXXXXXX	
С89н	WRARH4	Upper address setting register 4	R/W	XXXXXXX	
С8Ан	WRARL4	Lower address setting register 4	R/W	XXXXXXX	
С8Вн	WRDR4	Data setting register 4	R/W	XXXXXXX	
С8Сн	WRARH5	Upper address setting register 5	R/W	XXXXXXX	
C8Dн	WRARL5	Lower address setting register 5	R/W	XXXXXXX	
С8Ен	WRDR5	Data setting register 5	R/W	XXXXXXX	
С8Fн	WRARH6	Upper address setting register 6	R/W	XXXXXXX	
С90н	WRARL6	Lower address setting register 6	R/W	XXXXXXX	
С91н	WRDR6	Data setting register 6	R/W	XXXXXXXX	

• Description of write/read symbols :

R/W : read/write enabled

R : Read only W : Write only

Description of initial values :0 : This bit initialized to "0".

1 : This bit initialized to "1".

X : The initial value of this bit is not determined.M : The initial value of this bit is a mask option.

- : This bit is not used.

Note: Do not use reserved spaces.

■ ELECTRICAL CHARACTERISTICS

1. Absolute Maximum Ratings

(AVss = Vss = 0 V)

Darameter	Symbol	Rat	ing	Unit	Remarks	
Parameter	Symbol	Min	Max	Unit	Remarks	
	Vcc AVcc	Vss - 0.3	Vss + 4.0	V	MB89537/538 MB89537C/538C *1	
Supply voltage	AVR	Vss - 0.3	Vss + 4.0	V	MB89F538L	
Supply voltage	Vcc AVcc	Vss - 0.3	Vss + 6.0	V	MB89P538 - MB89PV530 *1	
	AVR	Vss-0.3	Vss + 6.0	V	1010091 0330	
Input voltage	Vı	Vss - 0.3	Vcc + 0.3	V	Other than P42, P43	
input voitage	VI	Vss - 0.3	Vss + 6.0	V	Only P42, P43	
Output voltage	Vo	Vss - 0.3	Vcc + 0.3	V	Other than P42, P43	
Output voltage	VO	Vss - 0.3	Vss + 6.0	V	Only P42, P43	
Maximum clamp current	I CLAMP	- 2.0	+ 2.0	mA	*2	
Total maximum clamp current	Σ ICLAMP	_	20	mA	*2	
"L" level maximum output current	loL	_	15	mA		
"L" level average output current	lolav		4	mA	Average value (operating current × operating duty)	
"L" level maximum total output current	ΣΙοι	_	100	mA		
"L" level average total output current	Σ lolav	_	40	mA	Average value (operating current × operating duty)	
"H" level maximum output current	Іон	_	-15	mA		
"H" level average output current	Іонач		-4	mA	Average value (operating current × operating duty)	
"H" level maximum total output current	ΣІон		-50	mA		
"H" level average total output current	ΣΙομαν	_	-20	mA	Average value (operating current × operating duty)	
Current consumption	P□		300	mW		
Operating temperature	TA	-40	+85	°C		
Storage temperature	Tstg	-55	+150	°C		

^{*1 :} AVcc and Vcc are to be used at the same potential. AVR should not exceed AVcc + 0.3 V.

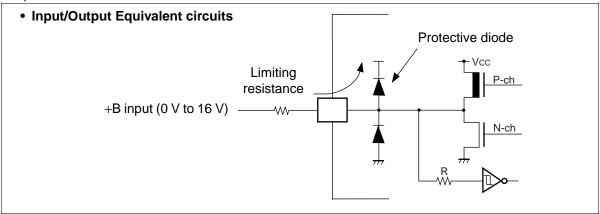
^{*2: •} Applicable to pins: P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40, P41, P44 to P47, P50 to P57, P60 to P64

[•] Use within recommended operating conditions.

[•] Use at DC voltage (current) .

(Continued)

- The +B signal should always be applied with a limiting resistance placed between the +B signal and the microcontroller.
- The value of the limiting resistance should be set so that when the +B signal is applied the input current to the microcontroller pin does not exceed rated values, either instantaneously or for prolonged periods.
- Note that when the microcontroller drive current is low, such as in the power saving modes, the +B input potential may pass through the protective diode and increase the potential at the Vcc pin, and this may affect other devices.
- Note that if a +B signal is input when the microcontroller current is off (not fixed at 0 V), the power supply is provided from the pins, so that incomplete operation may result.
- Note that if the +B input is applied during power-on, the power supply is provided from the pins and the resulting supply voltage may not be sufficient to operate the power-on result.
- Care must be taken not to leave the +B input pin open.
- Note that analog system input/output pins other than the A/D input pins (LCD drive pins, comparator input pins, etc.) cannot accept +B signal input.
- Sample recommended circuits :



WARNING: Semiconductor devices can be permanently damaged by application of stress (voltage, current, temperature, etc.) in excess of absolute maximum ratings. Do not exceed these ratings.

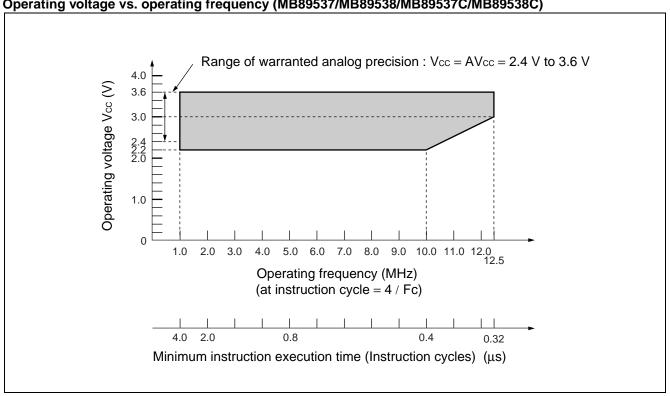
2. Recommended Operating Conditions

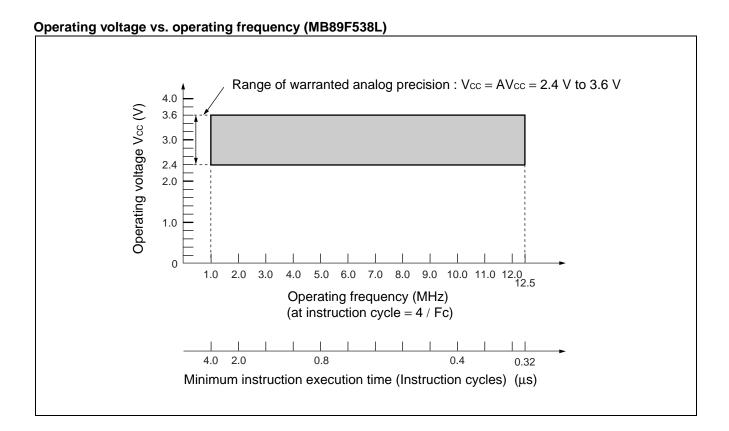
(AVss = Vss = 0 V)

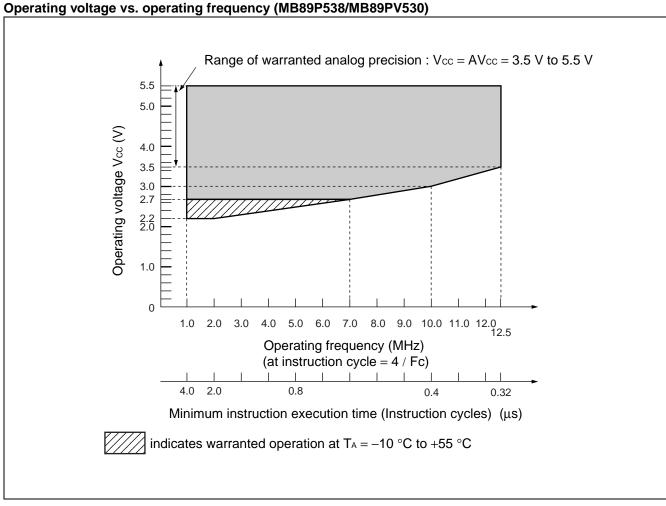
Parameter	Symbol	Value		Unit	Remarks	
i didilietei		Min	Max	Ullit	Remarks	
	Vcc, AVcc	2.2*	3.6	V	Range warranted for normal operation	MB89537/538 - MB89537C/
		1.5	3.6	V	RAM status in stop mode	538C
		2.4	3.6	V	Range warranted for normal operation	- MB89F538L
Supply voltage		1.5	3.6	V	RAM status in stop mode	WEGGI GGGE
		2.7*	5.5	V	Range warranted for normal operation	MB89P538
		1.5	5.5	V	RAM status in stop mode	MB89PV530
	AVR	2.4	AVcc	V		
Operating temperature	Та	-40	+85	°C		

^{*:} Varies according to frequency used, and instruction cycle. See "Operating voltage vs. operating frequency (MB89537/MB89538/MB89537C/MB89538C) and (MB89P538/ MB89PV530) " and "5. A/D Converter Electrical Characteristics".

Operating voltage vs. operating frequency (MB89537/MB89538/MB89537C/MB89538C)







WARNING: The recommended operating conditions are required in order to ensure the normal operation of the semiconductor device. All of the device's electrical characteristics are warranted when the device is operated within these ranges.

> Always use semiconductor devices within their recommended operating condition ranges. Operation outside these ranges may adversely affect reliability and could result in device failure.

> No warranty is made with respect to uses, operating conditions, or combinations not represented on the data sheet. Users considering application outside the listed conditions are advised to contact their FUJITSU representatives beforehand.

3. DC Characteristics

(AVcc = Vcc = 3.0 V, AVss = Vss = 0 V, $T_A = -40$ °C to +85 °C)

<u> </u>					Value		-	-40 °C (0 +65 °C)
Parameter	Symbol	Pin name	Condition	Min	Тур	Max	Unit	Remarks
	VıH	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P60 to P64, S11, SI2	_	0.7 Vcc	_	Vcc + 0.3	٧	
"H" level input voltage	Vihs	RST, MOD0, MOD1, INT20 to INT27, UCK1, UI1, INT10 to INT13, SCK1, EC, PWCK, PWC, SCK2, UCK2, UI2, ADST	_	0.8 Vcc	_	Vcc + 0.3	V	
	VIHSMB	SCL, SDA	_	Vss + 1.4	_	Vss + 5.5	V	With SMB input buffer selected*
	V _{IHI2C}	002, 007.	_	0.7 Vcc	_	Vss + 5.5	٧	With I ² C input buffer selected*
	VIL	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P60 to P64, SI1, SI2	_	Vss - 0.3	_	0.3 Vcc	٧	
"L" level input voltage		RST, MOD0, MOD1, INT20 to INT27, UCK1, UI1, INT10 to INT13, SCK1, EC, PWCK, PWC, SCK2, UCK2, UI2, ADST	_	Vss - 0.3	_	0.2 Vcc	V	
	VILSMB	SCL, SDA	_	Vss - 0.3	_	Vss + 0.6	V	With SMB input buffer selected*
	V _{ILI2C}	OOL, ODA	_	Vss - 0.3	_	0.3 Vcc	V	With I ² C input buffer selected*
Open drain	V _{D1}	P50 to P57		V 00		Vcc + 0.3	V	
output applied voltage	V _{D2}	P42, P43	_	Vss – 0.3	_	Vss + 5.5	V	
"H" level output voltage	Vон	P00 to P07, P10 to P17, P20 to P24, P30 to P37, P40, P41, P44 to P47	Iон = -2.0 mA	2.4	_	_	V	
output voltago		P25 to P27	Iон = -3.0 mA					
"L" level output voltage	Vol	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, RST	I _{OL} = 4.0 mA	_	_	0.4	V	
Input leak current (Hi-Z output leak current)	lu	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40 to P47, P50 to P57, P60 to P64	0.0 V < V _I < V _{CC}	-5	_	+5	μΑ	With no pull-up resistance specified

(Continued)

(AVcc = Vcc = 3.0 V, AVss = Vss = 0 V, $T_{\text{A}} = -40~^{\circ}\text{C}$ to +85 $^{\circ}\text{C})$

D		D'			Value			B =				
Parameter	Symbol	Pin name	Condition	Min	Тур	Max	Unit	Remarks				
Open drain output leak current	Інор	P42, P43	0.0 V < V _I < V _{SS} + 5.5 V	_	_	+5	μА					
Pull-up resistance	Rpull	P00 to P07, P10 to P17, P20 to P27, P30 to P37, P40, P41, P44 to P47, P60 to P64, RST	Vı = 0.0 V	25	50	100	kΩ	With pull-up resistance is selected. The RST signal is excluded.				
					6	10	mA	Normal operation				
	Icc1		$F_{\text{CH}} = 10.0 \; \text{MHz}$ $t_{\text{inst}} = 0.4 \; \mu \text{s}$	_	_	45	mA	FLASH memory programming/erase MB89F538L				
	Icc2		$F_{\text{CH}} = 10.0 \text{ MHz}$ $t_{\text{inst}} = 6.4 \ \mu\text{s}$		1.5	3	mA					
	Iccs ₁		$F_{\text{CH}} = 10.0 \text{ MHz}$ $t_{\text{inst}} = 0.4 \ \mu\text{s}$	_	2	4	mA	Sleep mode				
Iccs2	Iccs ₂		$F_{\text{CH}} = 10.0 \text{ MHz}$ $t_{\text{inst}} = 6.4 \ \mu\text{s}$		1	2	mA	Sleep mode				
	lccL		FcL = 32.768 kHz		1	3	mA	Sub mode MB89P538/PV530				
		Vcc	FcL = 32.768 kHz T _A = +25 °C		35	90	μА	Sub mode MB89F538L				
Supply current			FcL = 32.768 kHz	_	20	50	μА	Sub mode MB89537/538 MB89537C/538C				
ourion	Iccls		FcL = 32.768 kHz	_	15	30	μА	Sub, sleep modes Except MB89F538L				
	ICCLS		FcL = 32.768 kHz T _A = +25 °C	_	15	30	μА	Watch mode, main stop MB89F538L				
	Ісст							FcL = 32.768 kHz	_	5	15	μА
			FcL = 32.768 kHz T _A = +25 °C	_	5	15	μА	Sub, sleep modes MB89F538L				
	Іссн		T _A = +25 °C	_	1	5	μΑ	Sub, stop modes				
	la	AVcc	FcH = 10.0 MHz	_	1	3	mA	A/D conversion running				
	Іан		T _A = +25 °C	_	1	5	μΑ	A/D stopped				
Input capacitance	Cin	Except Vcc, Vss, AVcc, AVss	f = 1 MHz	_	5	15	pF					

^{*:} The MB89PV530/P538/F538L/537C/538C have a built-in I²C function, and a choice of input buffers by software setting. The MB89537/538 have no built-in I²C functions, and therefore this standard does not apply.

4. AC Characteristics

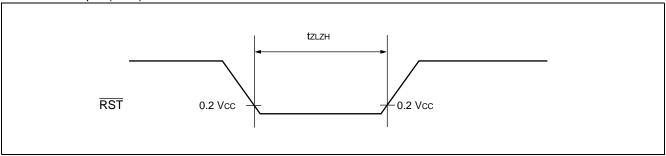
(1) Reset Timing

$$(Vcc = 3.0 \text{ V}, \text{ AVss} = \text{Vss} = 0 \text{ V}, \text{ T}_A = -40 \,^{\circ}\text{C to} +85 \,^{\circ}\text{C})$$

Parameter	Symbol	Condition	Va	Value		Remarks	
Farameter	Syllibol	Condition	Min	Max	Unit	Nemarks	
RST "L" pulse width	t zlzh	_	48 theyl	_	ns		

Notes: • theore is the main clock oscillator period.

• If the reset pulse applied to the external reset pin (\overline{RST}) does not meet the specifications, it may cause malfunctions. Use caution so that the reset pulse less than the specifications will not be fed to the external reset pin (\overline{RST}) .

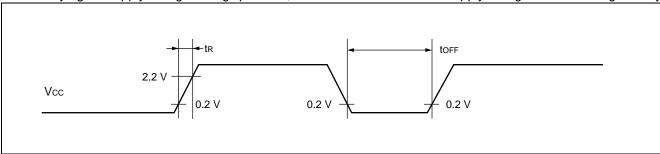


(2) Power-on Reset

(AVss = Vss = 0 V,
$$T_A = -40 \, ^{\circ}\text{C}$$
 to +85 $^{\circ}\text{C}$)

Parameter	Symbol	Condition	Value			Remarks
Faranielei	Symbol	Condition	Min	Max	Unit	Remarks
Power on time	t R	_	0.5	50	ms	
Power shutoff time	toff	_	1	_	ms	For repeated operation

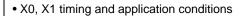
Note: Be sure that the power supply will come on within the selected oscillator stabilization period. Also, when varying the supply voltage during operation, it is recommended that the supply voltage be increased gradually.

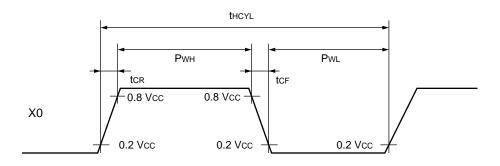


(3) Clock Timing Standards

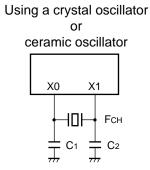
(AVss = Vss = 0 V,
$$T_A = -40$$
 °C to +85 °C)

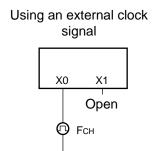
Domenication	Symbol Bin name		Condition		Value		11:4	Damania	
Parameter	Symbol	Pin name	Condition	Min	Тур	Max	Unit	Remarks	
Clock frequency	Fсн	X0, X1		1	_	12.5	MHz	Main clock	
Clock frequency	FcL	X0A, X1A		_	32.768		kHz	Sub clock	
Clock cycle time	t HCYL	X0, X1		80	_	1000	ns	Main clock	
Clock cycle time	t LCYL	X0A, X1A			30.5		μs	Sub clock	
Input clock pulse width	Pwh Pwl	X0	_	20	_	_	ns	External clock	
Input clock pulse width	Pwнн Pwll	X0A		_	15.2	_	μs	External clock	
Input clock rise, fall time	tcr tcr	Х0		_	_	10	ns	External clock	

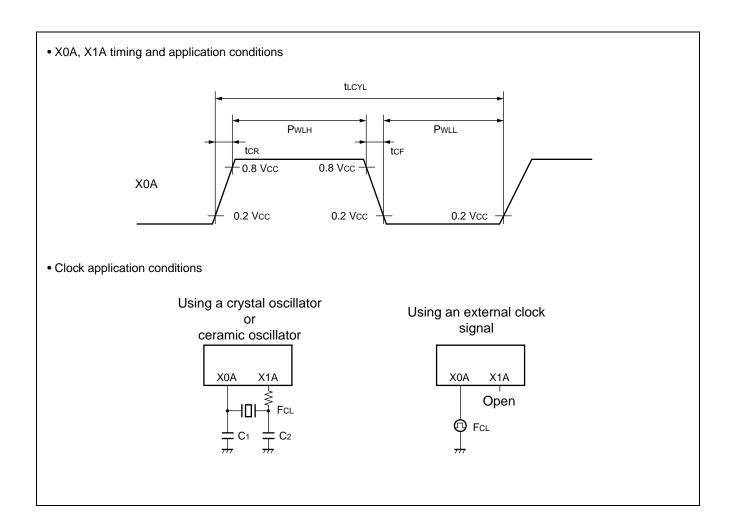




• Clock application conditions







(4) Instruction Cycle

(AVss = Vss = 0 V, $T_A = -40$ °C to +85 °C)

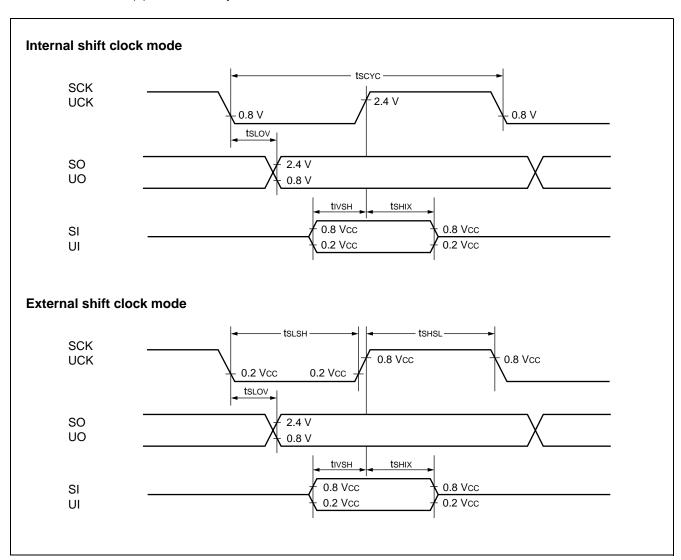
Parameter	Symbol	Rated value	Unit	Remarks
Instruction cycle (minimum instruction execution time)	t inst	4/Гсн, 8/Гсн, 16/Гсн, 64/Гсн	μs	Operating at FcH = 12.5 MHz (4/FcH) tinst = 0.32 μs
		2/FcL	μs	Operating at F _{CL} = 32.768 kHz t_{inst} = 61.036 μs

(5) Serial I/O Timing

(Vcc = 3.0 V, AVss = Vss = 0 V, $T_A = -40 \, ^{\circ}\text{C}$ to +85 $^{\circ}\text{C}$)

Parameter	Symbol Pin name		Condition	Val	lue	Unit	Remarks
raiailletei	Symbol	Finitianie	Condition	Min	Max	Oiiit	iveillai ks
Serial clock cycle time	t scyc	SCK, UCK		2 tinst	_	μs	
SCK↓→SO	t sLov	SCK, SO, UCK, UO	Internal clock	-200	+200	ns	
Valid SI→SCK↑	tıvsн	SI, SCK, UI, UCK	operation	200		ns	
SCK↑→ valid SI hold time	t shix	SCK, SI, UCK, UI		200		ns	
Serial clock "H" pulse width	t shsl	SCK, UCK		1 tinst		μs	
ÉSerial clock "L" pulse width	t slsh	SON, OOK	External	1 tinst	_	μs	
SCK↓→SO time	t sLov	SCK, SO, UCK, UO	clock	0	200	ns	
Valid SI→SCK↑	tıvsн	SI, SCK, UI, UCK	operation	200		ns	
$SCK \uparrow \rightarrow valid SI hold time$	t shix	SCK, SI, UCK, UI		200		ns	

Note: For tinst see " (4) Instruction Cycle".

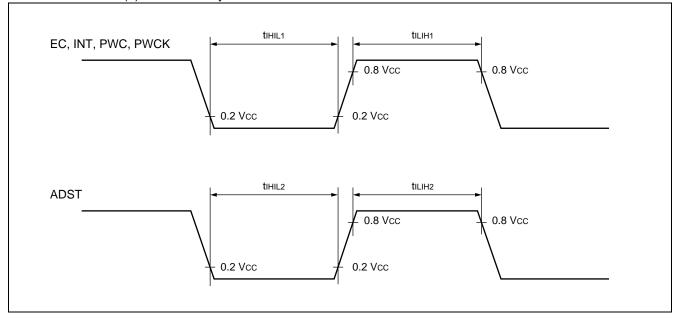


(6) Peripheral Input Timing

(Vcc = 3.0 V, AVss = Vss = 0 V, $T_A = -40$ °C to +85 °C)

Parameter	Symbol	Pin name	Condition	Val	ue	Unit	Remarks
rarameter	Syllibol	Fili lialile	Condition	Min	Max	Oiii	Nemarks
Peripheral input "H" level pulse width 1	t ıLıH1	INT10 to INT13, INT20 to INT27,	_	2 tinst	_	μs	
Peripheral input "L" level pulse width 1	t _{IHIL1}	EC, PWC, PWCK		2 tinst	_	μs	
Peripheral input "H" level pulse width 2	t ıLıH2	ADST		2 ⁸ t _{inst}	_	μs	
Peripheral input "L" level pulse width 2	t ıHIL2	ADST	_	28 tinst		μs	

Note: For t_{inst} see " (4) Instruction Cycle".



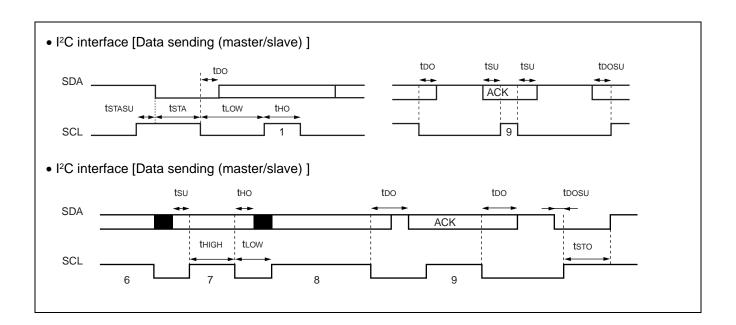
(7) I²C Timing

 $(Vcc = 3.0 \text{ V}, \text{ AVss} = \text{Vss} = 0 \text{ V}, \text{ T}_A = -40 \, ^{\circ}\text{C} \text{ to } +85 \, ^{\circ}\text{C})$

Parameter	Symbol	Pin	Condition	Val	lue	Unit	Remarks
raiametei	Syllibol	name	Condition	Min	Max	Oilit	iveillai va
Start condition output	t sta	SCL SDA	_	$\begin{array}{c} 1 \; / \; 4 \; t_{inst} \times \\ m \times n - 20 \end{array}$	$\begin{array}{c} 1 \ / \ 4 \ t_{inst} \times \\ m \times n + 20 \end{array}$	ns	Master only
Stop condition output	t sto	SCL SDA	_	$\begin{array}{c} 1 \ / \ 4 \ t_{inst} \times \\ (m \times n + 8) \ - 20 \end{array}$	$\begin{array}{c} 1 \ / \ 4 \ t_{inst} \times \\ (m \times n + 8) \ + 20 \end{array}$	ns	Master only
Start condition detection	t sta	SCL SDA	_	1 / 4 t _{inst} × 6 + 40		ns	
Stop condition detection	t sto	SCL SDA	_	1 / 4 t _{inst} × 6 + 40	_	ns	
Restart condition output	t stasu	SCL SDA	_	$\begin{array}{c} 1 \; / \; 4 \; t_{inst} \times \\ (m \times n + 8) \; - 20 \end{array}$	$\begin{array}{c} 1 \ / \ 4 \ t_{inst} \times \\ (m \times n + 8) \ + 20 \end{array}$	ns	Master only
Restart condition detection	t stasu	SCL SDA	_	1 / 4 t _{inst} × 4 + 40		ns	
SCL output "L" width	tLOW	SCL	_	$\begin{array}{l} 1 \; / \; 4 \; t_{inst} \times \\ m \times n - 20 \end{array}$	$\begin{array}{c} 1 \; / \; 4 \; t_{inst} \times \\ m \times n \; + \; 20 \end{array}$	ns	Master only
SCL output "H" width	t HIGH	SCL	_	$\begin{array}{c} 1 \ / \ 4 \ t_{inst} \times \\ (m \times n + 8) \ - 20 \end{array}$	$\begin{array}{c} 1 \ / \ 4 \ t_{inst} \times \\ (m \times n + 8) \ + 20 \end{array}$	ns	Master only
SDA output delay time	t₀o	SDA		$1~/~4~t_{\text{inst}}\times 4-20$	$1~/~4~t_{inst}\times 4+20$	ns	
Setup after SDA output interrupt interval	t DOSU	SDA	_	$1 \ / \ 4 \ t_{\text{inst}} \times 4 - 20$	_	ns	
SCL input "L" width	t LOW	SCL	_	$1 / 4 t_{inst} \times 6 + 40$	_	ns	
SCL input "H" width	t HIGH	SCL		$1 / 4 t_{inst} \times 2 + 40$	_	ns	
SDA input setup	t su	SDA		40		ns	_
SDA input hold	tно	SDA	_	0	_	ns	

Notes: • For t_{inst} see " (4) Instruction Cycle".

- The value "m" in the above table is the value from the shift clock frequency setting bits (CS4-CS3) in the clock control register "ICCR". For details, refer to the register description in the hardware manual.
- The value 'n' in the above table is the value from the shift clock frequency setting bits (CS2-CS0) in the clock control register "ICCR". For details, refer to the register description in the hardware manual.
- toosu appears when the interrupt period is longer than the SCL "L" width.
- The rated values for SDA and SCL assume a start up time of 0 ns.



5. A/D Converter Electrical Characteristics

(1) MB89537/538/537C/538C

 $(Vcc = 2.4 V to 3.6 V, AVss = Vss = 0 V, T_A = -40 °C to +85 °C)$

Parameter	Symbol	Pin name	Condition		Value		Unit	Remarks
raiametei	Syllibol	r III IIaiiie	Condition	Min	Тур	Max	Oilit	Nemarks
Resolution capability			_	_	_	10	bit	
Total error				_	_	±3.0	LSB	
Linear error				_	_	±2.5	LSB	
Differential linear error				_	_	±1.9	LSB	
Zero transition voltage	Vот		AVR = AVcc	AVss-1.5 LSB	AVss+0.5 LSB	AVss+2.5 LSB	mV	AVcc = Vcc
Full scale transition voltage	V _{FST}			AVR-3.5 LSB	AVR – 1.5 LSB	AVR+1.5 LSB	mV	
Inter-channel variation				_	_	4.0	LSB	
Conversion time				_	60 tinst	_	μs	*
Sampling time				_	16 tinst	_	μs	
Analog input current	Iain	AN0 to		_	_	10	μΑ	
Analog input voltage	Vain	AN7		AVss	_	AVR	V	
Reference voltage	_			AVss + 2.4	_	AVcc	V	
Reference voltage	IR	AVR	A/D running	_	200	_	μΑ	
supply current	I _{RH}		A/D off			5	μΑ	

^{*:} Includes sampling time

(2) MB89F538L

(Vcc = 2.4 V to 3.6 V, AVss = Vss = 0 V, $T_A = -40$ °C to +85 °C)

Parameter	Symbol	Pin name	Condition		Value		Unit	Remarks	
i arameter	Symbol	i iii iiaiiie	Condition	Min	Тур	Max	Oilit	INCIII ai NS	
Resolution capability			_	_	_	10	bit		
Total error				_	_	±3.0	LSB		
Linear error				_	_	±2.5	LSB		
Differential linear error				_	_	±1.9	LSB		
Zero transition voltage	Vот		AVR = AVcc	AVss-1.5 LSB	AVss+0.5 LSB	AVss+2.5 LSB	mV	AVcc = Vcc	
Full scale transition voltage	VFST				AVR-3.5 LSB	AVR – 1.5 LSB	AVR+1.5 LSB	mV	
Inter-channel variation				_	_	4.0	LSB		
Conversion time				_	60 tinst	_	μs	*	
Sampling time				_	16 t _{inst}	_	μs		
Analog input current	IAIN	AN0 to		_	_	10	μΑ		
Analog input voltage	Vain	AN7		0	_	AVR	V		
Reference voltage	_			AVss + 2.4	_	AVcc	V		
Reference voltage	IR	AVR	A/D running	_	200	_	μΑ		
supply current	IRH		A/D off	_	_	5	μΑ		

^{*:} Includes sampling time

(3) MB89P538/PV530

(Vcc = 2.4 V to 3.6 V, AVss = Vss = 0 V, $T_A = -40$ °C to +85 °C)

Parameter	Symbol	Pin name	Condition		Value		Unit	Remarks
raiametei	Syllibol	r III IIaiiie	Condition	Min	Тур	Max	Ollit	Nemarks
Resolution capability				_	_	10	bit	
Total error				_	_	±3.0	LSB	
Linear error				_	_	±2.5	LSB	
Differential linear error				_	_	±1.9	LSB	
Zero transition voltage	Vот	_	AVR = AVcc	AVss-1.5 LSB	AVss+0.5 LSB	AVss+2.5 LSB	mV	AVcc = Vcc
Full scale transition voltage	V _{FST}			AVR-3.5 LSB	AVR – 1.5 LSB	AVR+1.5 LSB	mV	
Inter-channel variation				_	_	4.0	LSB	
Conversion time				_	60 tinst	_	μs	*
Sampling time				_	16 tinst	_	μs	
Analog input current	Iain	AN0 to		_	_	10	μΑ	
Analog input voltage	Vain	AN7		0	_	AVR	V	
Reference voltage	_			AVss + 3.5	_	AVcc	V	
Reference voltage	IR	AVR	A/D running	_	400	_	μΑ	
supply current	IRH		A/D off	_	_	5	μΑ	

^{*:} Includes sampling time

(4) A/D Converter Terms and Definitions

Resolution

The level of analog variation that can be distinguished by the A/D converter.

• Linear error (unit : LSB)

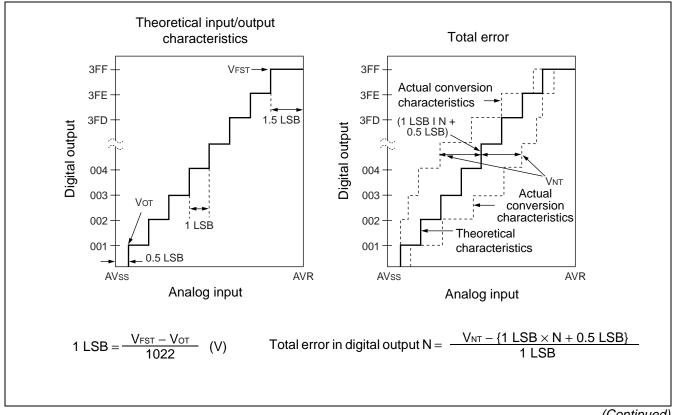
The deviation between the value along a straight line connecting the zero transition point ("00 0000 0000" ←→"00 0000 0001") of a device and the full-scale transition point ("11 1111 1110" \leftarrow "11 1111 1111"), compared with the actual conversion values obtained.

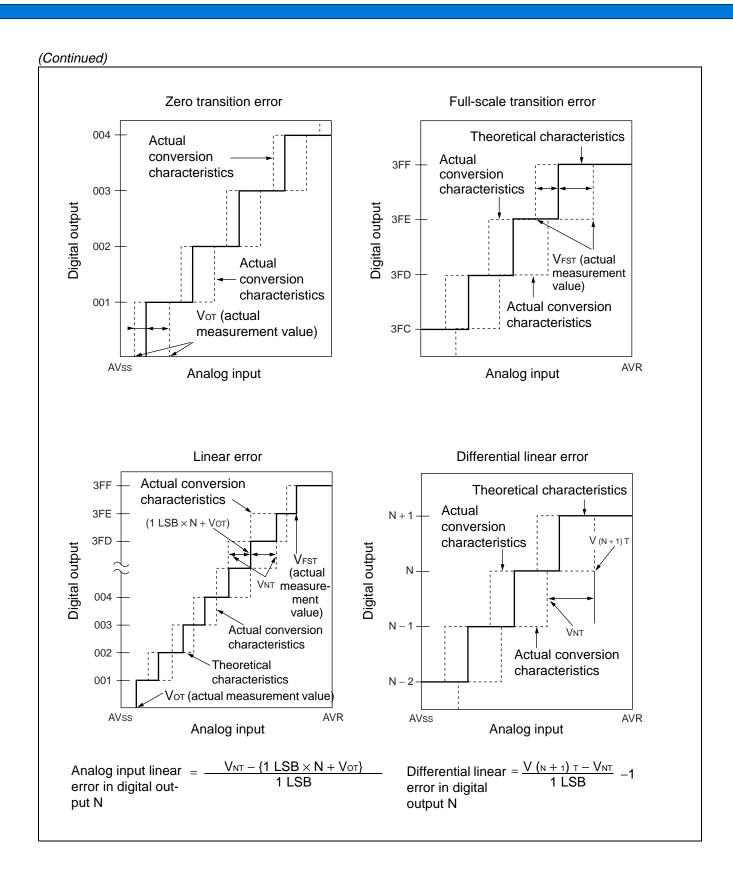
• Differential linear error (Unit : LSB)

The deviation from the theoretical input voltage required to produce a change of 1 LSB in output code.

• Total error (Unit : LSB)

The difference between theoretical conversion value and actual conversion value.

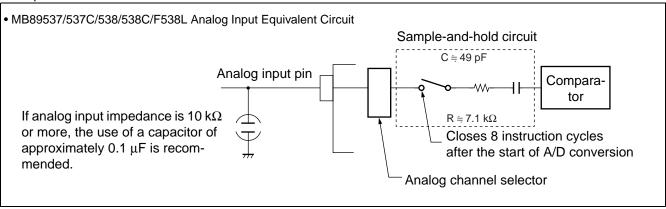


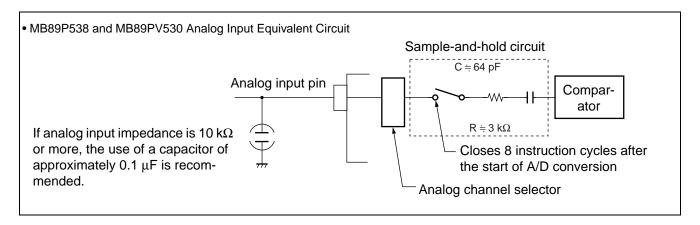


(5) Precautionary Information

• Input Impedance of Analog Input Pins

The A/D converter has a sample & hold circuit as shown below, which uses a sample-and-hold capacitor to obtain the voltage at the analog input pin for 8 instruction cycles following the start of A/D conversion. For this reason if the external circuits providing the analog input signal have high output impedance, the analog input voltage may not stabilize within the analog input sampling time. It is therefore recommended that the output impedance of external circuits be reduced to 10 k Ω or less.





About error

The smaller the absolute value |AVR - AVss| is, the greater the relative error becomes.

6. Flash Memory

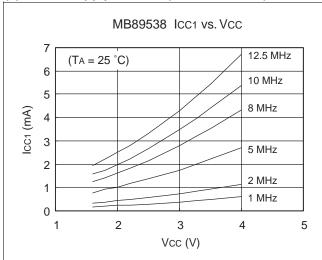
• Flash memory programming/erase characteristics

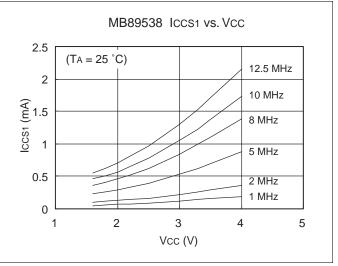
Parameter		Conditions	Value			Unit	Remarks
			Min	Тур	Max		Remarks
Sector erase time	Per 1 sector, Constant value inde- pendent with sector ca- pacitance	T _A = +25 °C, Vcc = 3.3 V	_	1	15	S	*
Program- ming time	Per 1 byte			8	3600	μs	
Chip erase time			_	5	_	S	*
Program/Erase cycle		_	10,000	_	_	cycle	

^{*:} Excludes internal programming time before erase.

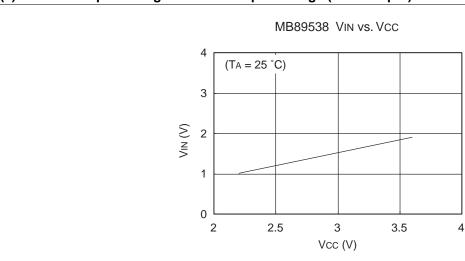
■ EXAMPLE CHARACTERISTICS

(1) Power Supply Current (External Clock)

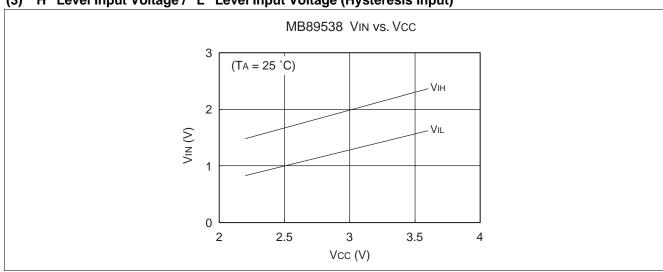


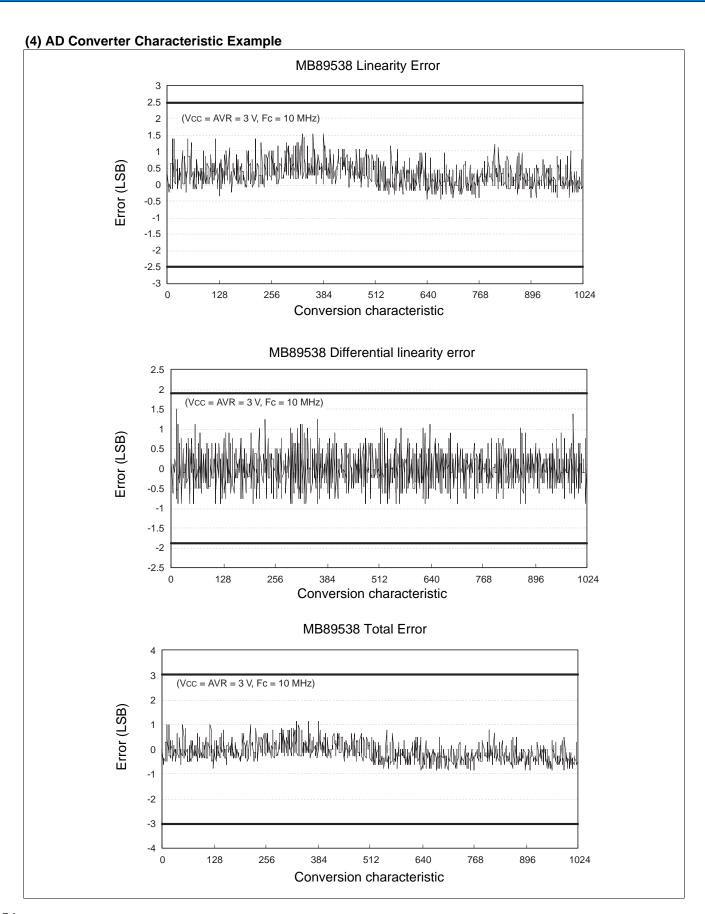


(2) "H" Level Input Voltage/ "L" Level Input Voltage (CMOS Input)



(3) "H" Level Input Voltage / "L" Level Input Voltage (Hysteresis Input)





■ MASK OPTIONS

No	Part number	MB89537 MB89537C MB89538 MB89538C	MB89F538L-101 MB89F538L-201	MB89P538-101 MB89P538-201	MB89PV530-101 MB89PV530-201
	Method of specification	Specify at time of mask order	Setting not possible	Setting not possible	Setting not possible
1	Main clock Select oscillator stabilization wait period (FcH * = 10 MHz) approx.2 ¹⁴ /FcH * (approx.1.6 ms) approx.2 ¹⁷ /FcH * (approx.13.1 ms) approx.2 ¹⁸ /FcH * (approx.26.2 ms)	Selection available	2 ¹⁸ /F _{CH} * (арргох. 26.2 ms)	2 ¹⁸ /F _{CH} * (approx. 26.2 ms)	2 ¹⁸ /F _{сн} * (approx. 26.2 ms)
2	Clock mode selection • 2-system clock mode • 1-system clock mode	Selection available	101 : 1-system clock mode 201 : 2-system clock mode		

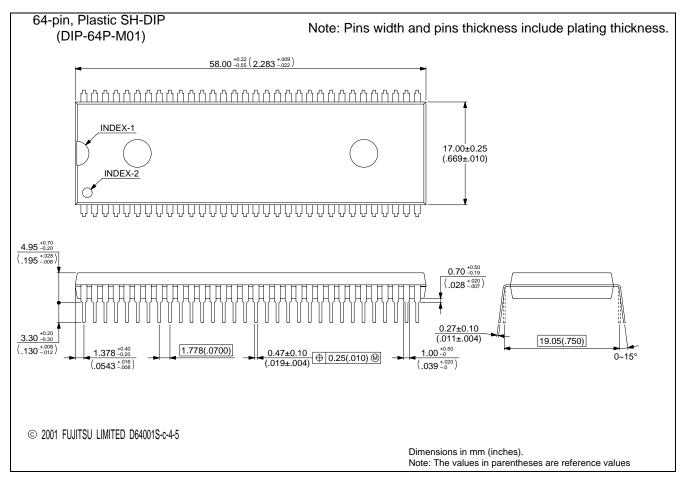
^{*:} Fch: Main clock frequency

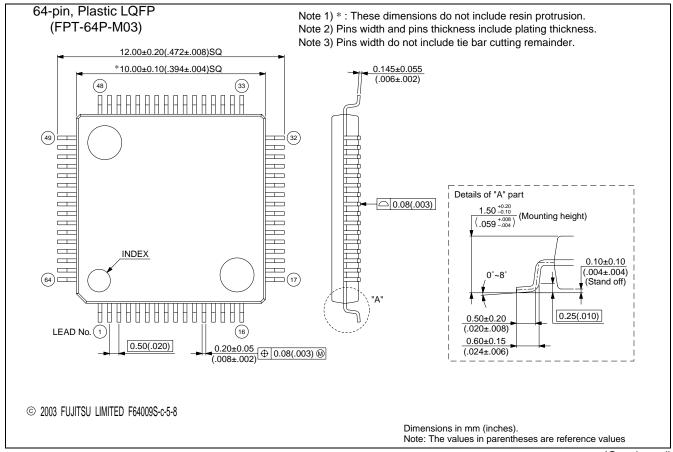
■ ORDERING INFORMATION

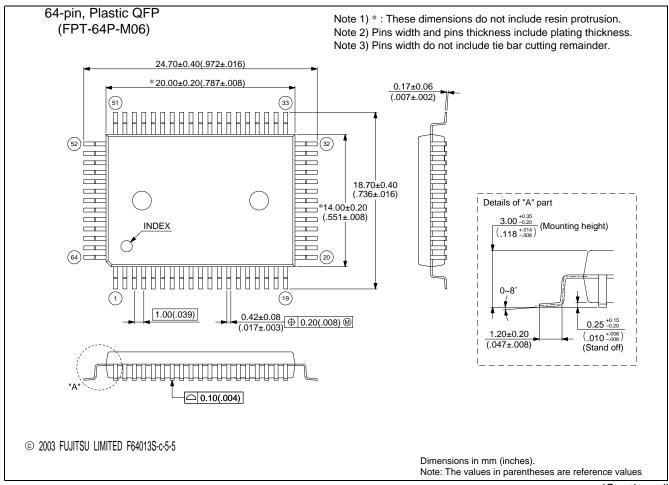
Part number	Package	Remarks
MB89537P MB89537CP MB89538P MB89538CP MB89F538L-101P MB89F538L-201P MB89P538-101P MB89P538-201P	DIP-64P-M01	MB89537P and MB89538P do not have I ² C functions.
MB89537PF MB89537CPF MB89538PF MB89538CPF MB89F538L-101PF MB89F538L-201PF MB89P538-101PF MB89P538-201PF	FPT-64P-M06	MB89537PF and MB89538PF do not have I ² C functions.
MB89537PFM MB89537CPFM MB89538PFM MB89538CPFM MB89F538L-101PFM MB89F538L-201PFM MB89P538-101PFM MB89P538-201PFM	FPT-64P-M09	MB89537PFM and MB89538PFM do not have I ² C functions.
MB89537PFV MB89537CPFV MB89538PFV MB89538CPFV	FPT-64P-M03	MB89537PFV and MB89538PFV do not have I ² C functions.
MB89F538L-101PV4 MB89F538L-201PV4	LCC-64P-M19	
MB89F538-101PV* MB89F538-201PV*	LCC-64P-M16*	
MB89PV530C-101 MB89PV530C-201	MDP-64C-P02	
MB89PV530CF-101 MB89PV530CF-201	MQP-64C-P01	

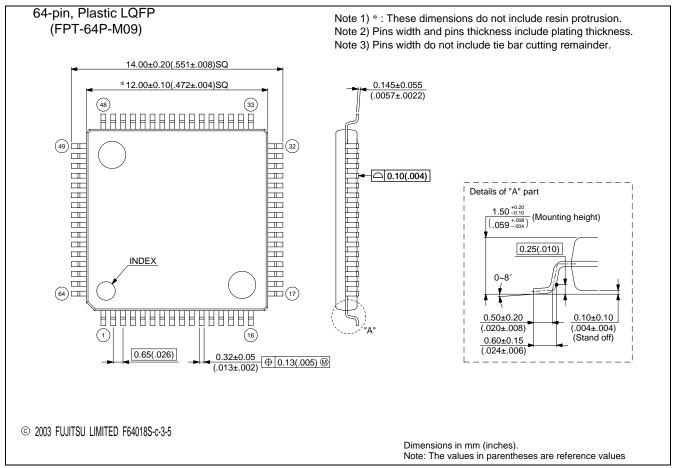
^{* :} Only for ES

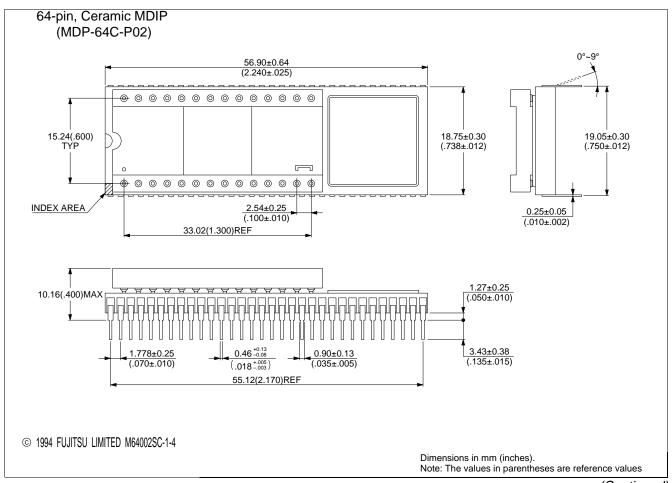
■ PACKAGE DIMENSIONS

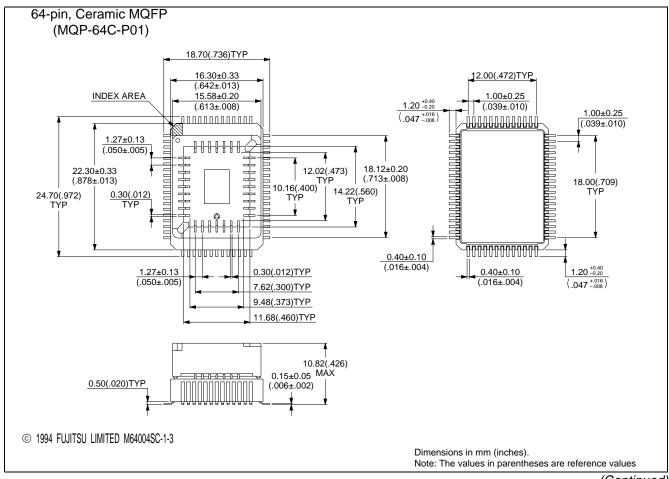


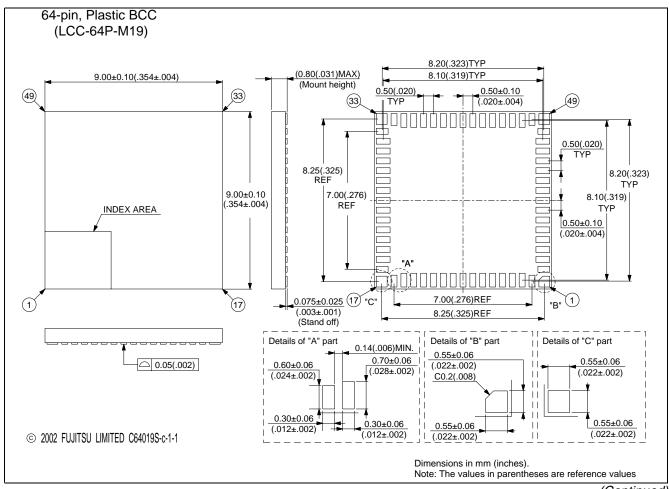


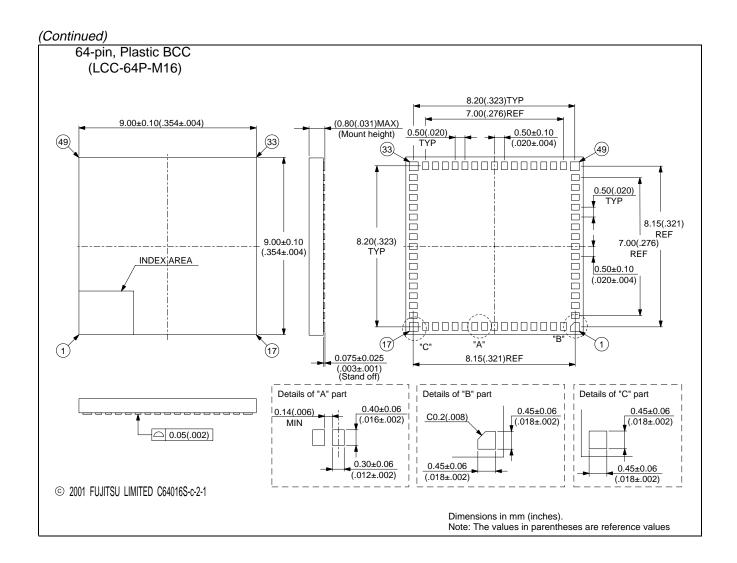












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